

PH150A280-*

EVALUATION DATA

型式データ

INDEX

	PAGE
1. 評価方法 Evaluation Method	
1.1 測定回路 Measurement Circuits	T-1
(1) 静特性、過電流保護特性、出力リップル・ノイズ波形 Steady state characteristics, Over current protection (OCP) characteristics, and Output ripple and noise waveform	
(2) 過渡応答、過電圧保護特性、その他 Dynamic response, Over voltage protection (OVP) characteristics and Other characteristics	
(3) 入力サージ電流（突入電流）特性 Inrush current characteristics	
(4) EMI 特性 Electro-Magnetic Interference characteristics	
1.2 使用測定機器 List of equipment used	T-3
2. 特性データ Characteristics	
2.1 静特性 Steady state data	
(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift	T-4
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧 Output voltage and Output ripple and noise voltage vs. Input voltage	T-6
(3) 入力電流、効率 対 出力電流 Input current and Efficiency vs. Output current	T-8
(4) 効率 対 入力電圧 Efficiency vs. Input voltage	T-10
(5) 効率 対 ベースプレート温度 Efficiency vs. Base-plate temperature	T-12
(6) 起動、停止電圧特性 Start and Stop voltage characteristics	T-14
2.2 待機電力特性 Standby power characteristics	T-16
2.3 通電ドリフト特性 Warm up voltage drift characteristics	T-18
2.4 過電流保護特性 Over current protection (OCP) characteristics	T-20
2.5 過電圧保護特性 Over voltage protection (OVP) characteristics	T-22
2.6 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics	T-24
2.7 過渡応答(負荷急変)特性 Dynamic load response characteristics	T-32
2.8 入力サージ電流(突入電流)特性 Inrush current characteristics	T-34
2.9 出力リップル・ノイズ波形 Output ripple and noise waveform	T-35
2.10 EMI特性 Electro-Magnetic Interference characteristics	T-37
使用記号 Terminology used	

Definition

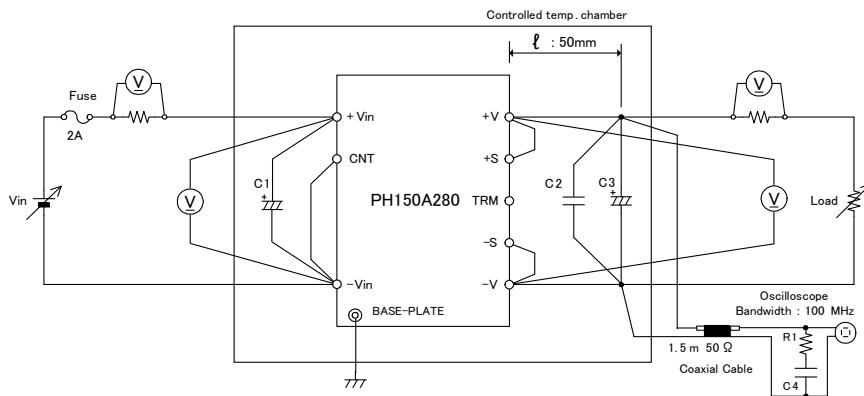
Vin	入力電圧	Input voltage
Vo	出力電圧	Output voltage
Vcnt	CNT電圧	CNT voltage
Iin	入力電流	Input current
Io	出力電流	Output current
Tbp	ベースプレート温度	Base-plate temperature
Ta	周囲温度	Ambient temperature
f	周波数	Frequency

1. 評価方法 Evaluation Method

1.1 測定回路 Measurement Circuits

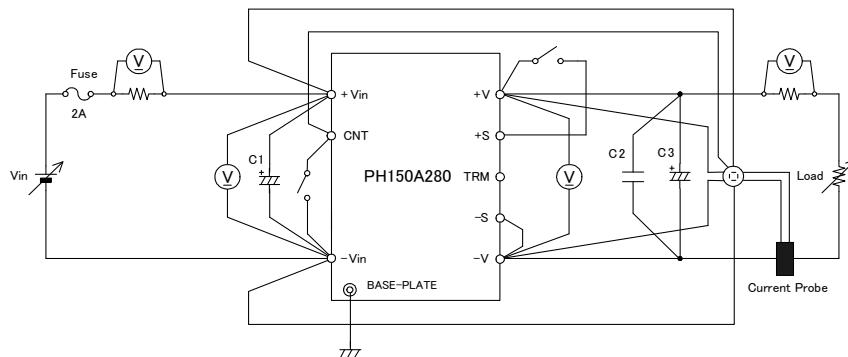
(1) 静特性、過電流保護特性、出力リップル・ノイズ波形

Steady state characteristics, Over current protection (OCP) characteristics, and Output ripple and noise waveform



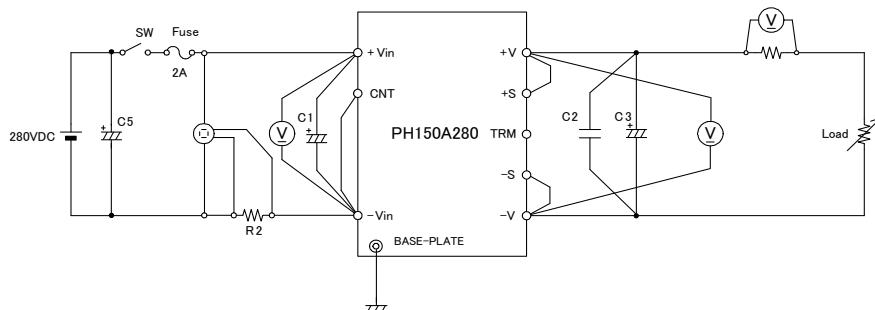
(2) 過渡応答、過電圧保護特性、その他

Dynamic response, Over voltage protection (OVP) characteristics and Other characteristics



(3) 入力サージ電流（突入電流）特性

Inrush current characteristics



C1 : 22uF Electrolytic Capacitor

C2 : 2.2μF Ceramic Capacitor

C3 : 12V-560uF Electrolytic Capacitor

: 24V-220uF Electrolytic Capacitor

: 48V-220uF×2series Electrolytic Capacitor

C4 : 4700pF Ceramic Capacitor

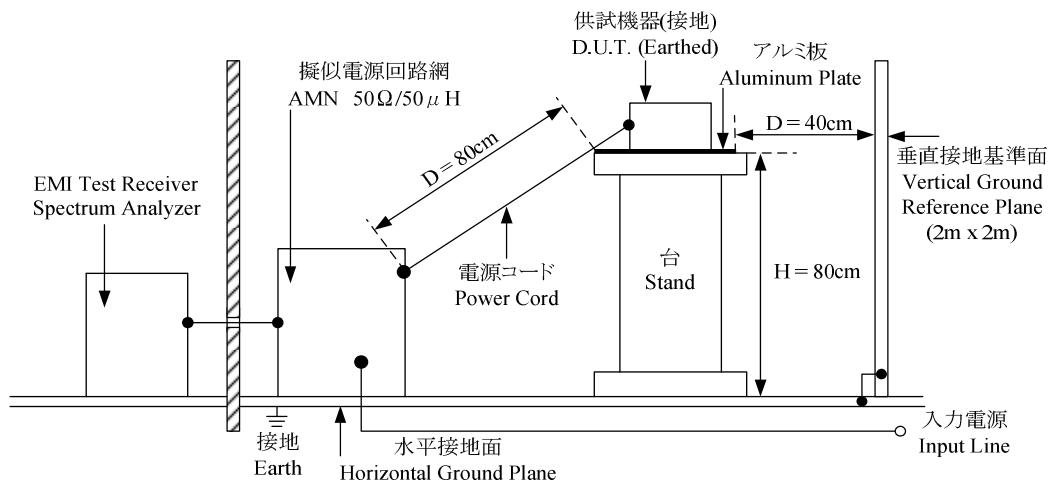
C5 : 8000uF Electrolytic Capacitor

R1 : 50Ω

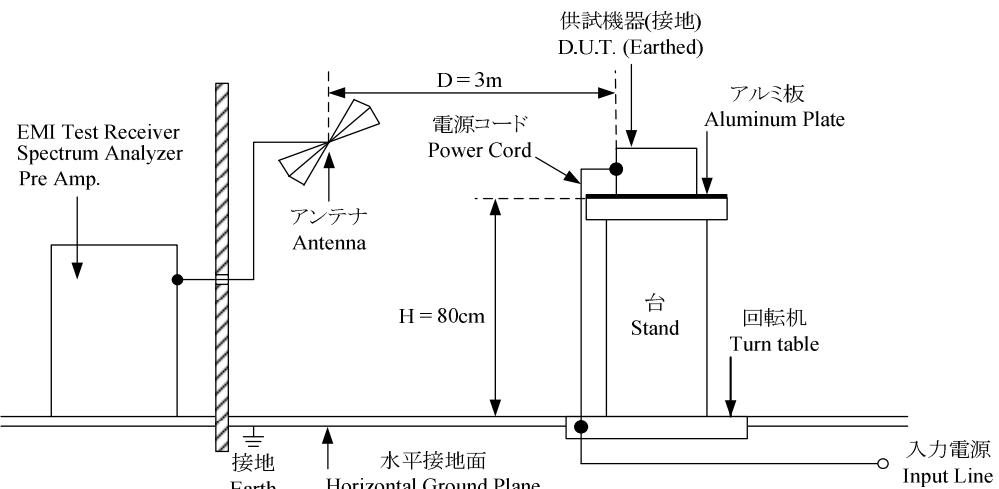
R2 : 0.01Ω

(4) EMI特性 Electro-Magnetic Interference characteristics

(a) 雑音端子電圧(帰還ノイズ) Conducted Emission Noise



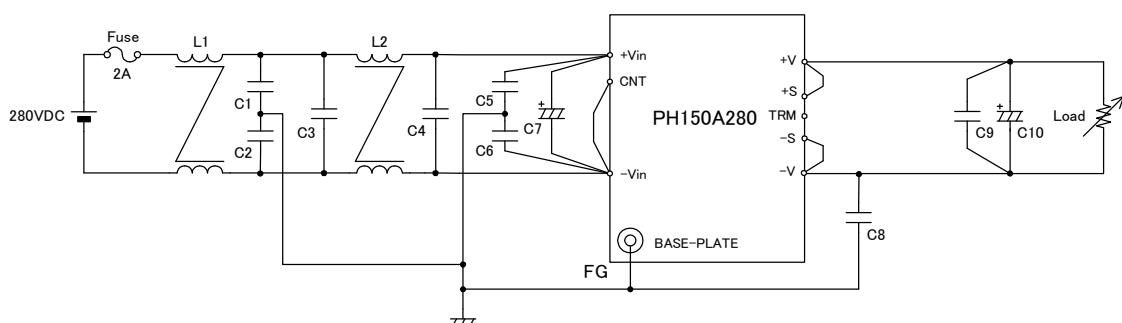
(b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



*入出力ケーブルとしてシールドケーブルを使用
Shielded cable used to input and output cable.

VCCI class A対応アプリケーションシステム

VCCI class A application system



C1,C2 : 470pF Ceramic Capacitor

C3 : 1.5μF Film Capacitor

C4 : 1.5μF Film Capacitor

C5,C6 : 2200pF Ceramic Capacitor

C7 : 22uF Electrolytic Capacitor

C8 : 0.022μF Ceramic Capacitor

C9 : 2.2μF Ceramic Capacitor

C10 : 12V-560uF Electrolytic Capacitor

: 24V-220uF Electrolytic Capacitor

: 48V-220uF×2series Electrolytic Capacitor

L1 : 0.6mH

L2 : 3.0mH

1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	AC POWER SUPPLY	KIKUSUI	PCR2000L
2	DYNAMIC DUMMY LOAD	Chrome	63030
3	DUMMY LOAD	ARCOL	HS50 SERIES
4	DATA ACQUISITION / SWITCH UNIT	AGILENT	34970A
5	SHUNT RESISTER	YOKOGAWA ELECT.	2215
6	CONTROLLED TEMP. CHAMBER	ESPEC CORP.	SH-661
7	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA	DLM2054
8	CURRENT PROBE	YOKOGAWA	701932
9	EMI TEST RECEIVER SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESCI
10	PRE AMP.	SONOMA	310N
11	AMN	SCHWARZBECK	NNLK8121
12	ANTENNA(BI-LOG ANTENNA)	TESEQ	CBL6111D

2. 特性データ Characteristics

2.1 静特性 Steady state data

(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

12V

1. Line regulation and Load regulation

Condition Tbp : 25°C

Io \ Vin	200VDC	280VDC	380VDC	425VDC	Line regulation	
0%	11.997V	11.997V	11.998V	11.997V	1mV	0.008%
50%	11.994V	11.995V	11.992V	11.991V	4mV	0.033%
100%	11.993V	11.995V	11.994V	11.993V	2mV	0.017%
Load regulation	4mV	2mV	6mV	6mV		
	0.033%	0.017%	0.050%	0.050%		

2. Temperature drift

Conditions Vin : 280VDC

Io : 100%

Tbp	-40°C	+25°C	+100°C	Temperature stability	
Vo	11.926V	11.995V	11.980V	69mV	0.575%

24V

1. Line regulation and Load regulation

Condition Tbp : 25°C

Io \ Vin	200VDC	280VDC	380VDC	425VDC	Line regulation	
0%	23.885V	23.886V	23.886V	23.884V	2mV	0.008%
50%	23.878V	23.882V	23.882V	23.881V	4mV	0.017%
100%	23.878V	23.881V	23.880V	23.878V	3mV	0.013%
Load regulation	7mV	5mV	6mV	6mV		
	0.029%	0.021%	0.025%	0.025%		

2. Temperature drift

Conditions Vin : 280VDC

Io : 100%

Tbp	-40°C	+25°C	+100°C	Temperature stability	
Vo	23.773V	23.881V	23.838V	108mV	0.450%

(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

48V

1. Line regulation and Load regulation Condition Tbp : 25°C

Io \ Vin	200VDC	280VDC	380VDC	425VDC	Line regulation	
0%	47.712V	47.712V	47.713V	47.714V	2mV	0.004%
50%	47.703V	47.705V	47.707V	47.709V	6mV	0.013%
100%	47.704V	47.706V	47.707V	47.708V	4mV	0.008%
Load regulation	9mV	7mV	6mV	6mV		
	0.019%	0.015%	0.013%	0.013%		

2. Temperature drift Conditions Vin : 280VDC

Io : 100%

Tbp	-40°C	+25°C	+100°C	Temperature stability	
Vo	47.567V	47.706V	47.739V	173mV	0.360%

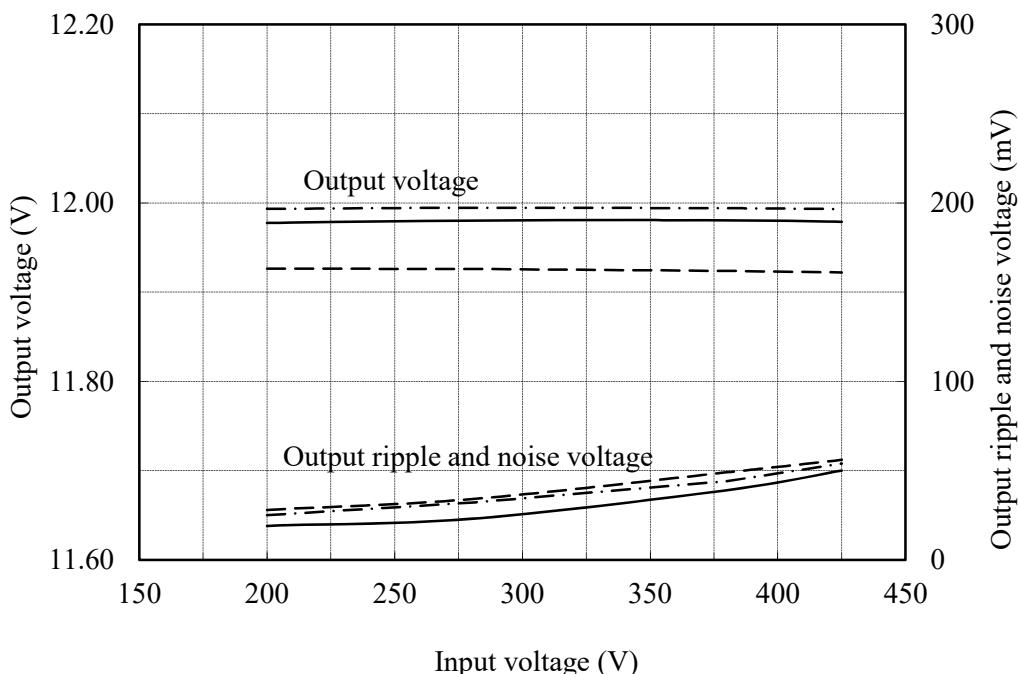
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

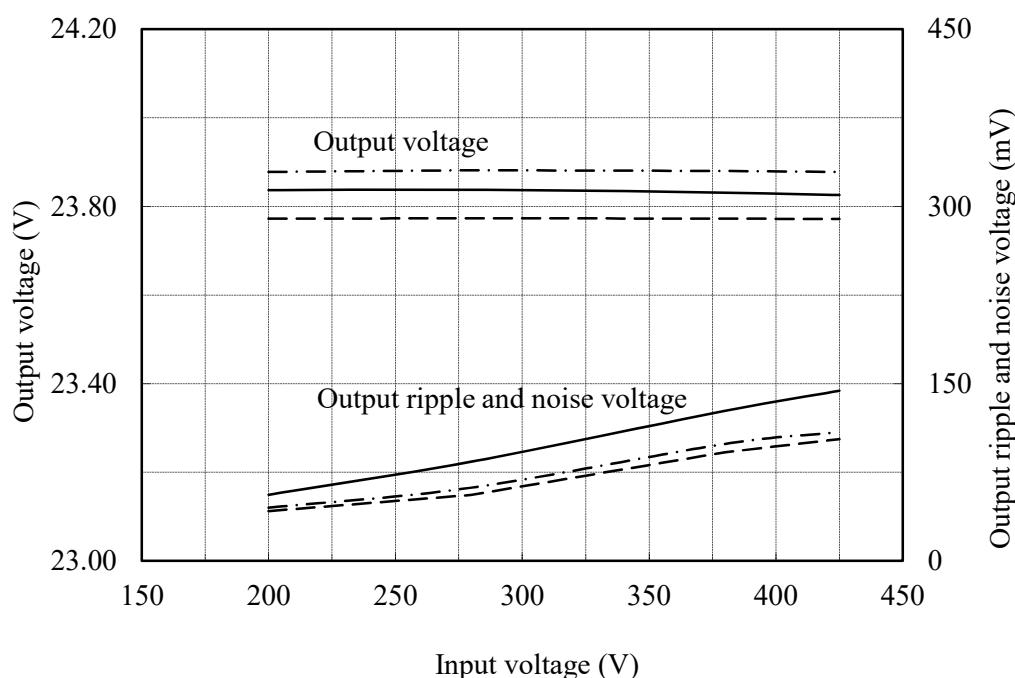
Conditions

I_o	: 100 %	- - -
T _{bp}	: -40 °C	- - -
	: 25 °C	- - -
	: 100 °C	—

12V



24V

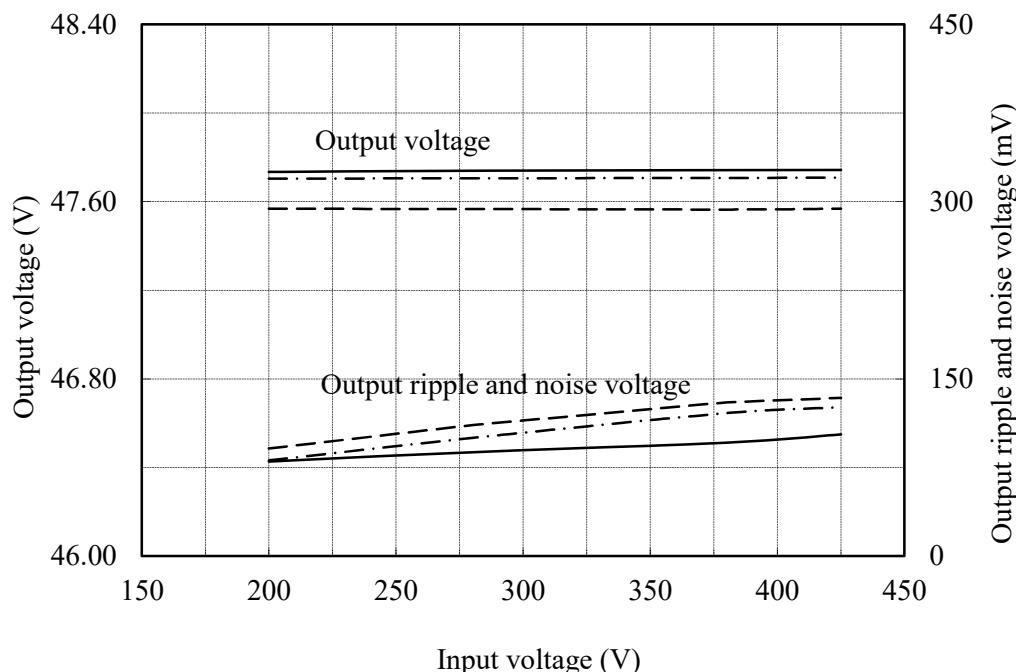


(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

Conditions Io : 100 %
 Tbp : -40 °C -----
 : 25 °C - - - -
 : 100 °C ——————

48V



(3) 入力電流、効率 対 出力電流

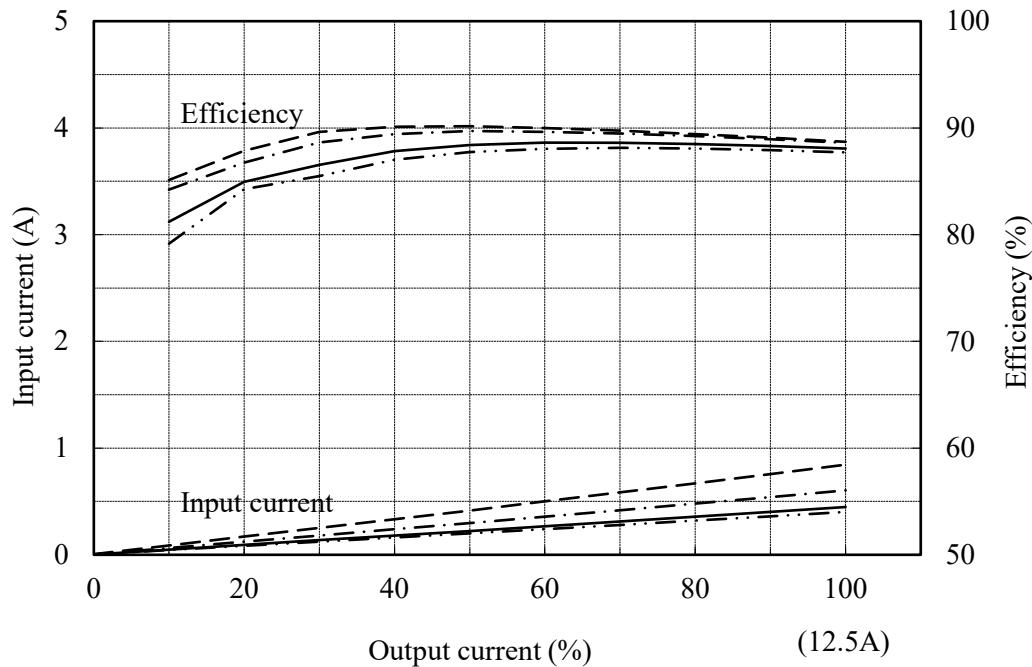
Input current and Efficiency vs. Output current

Conditions

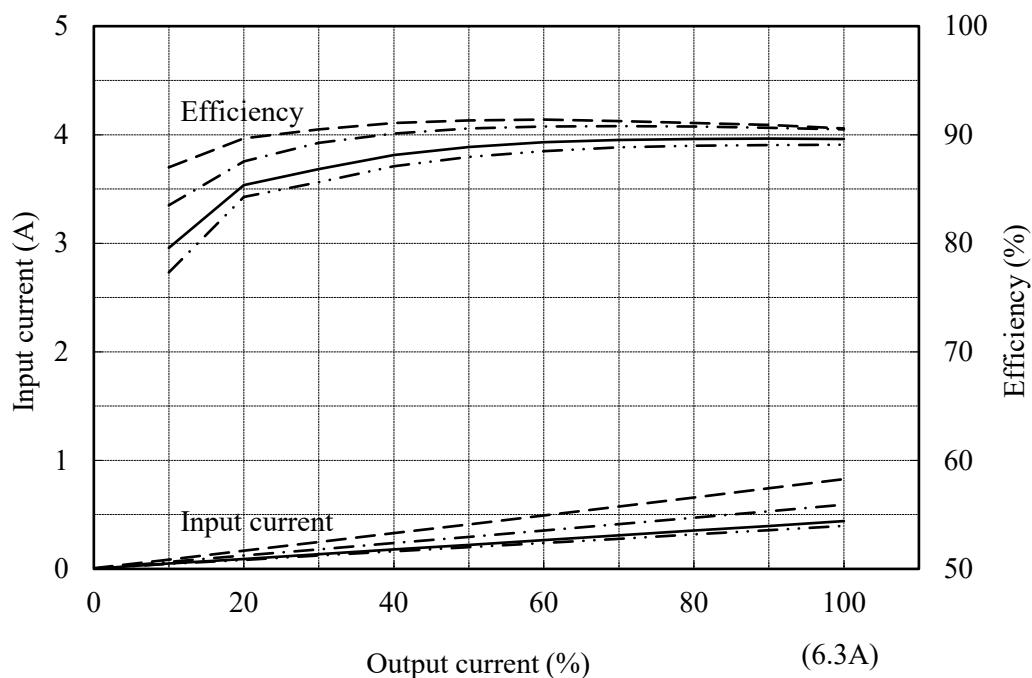
Vin :	200 VDC	-----
:	280 VDC	- - - -
:	380 VDC	———
:	425 VDC	- · - -

Tbp : 25 °C

12V



24V

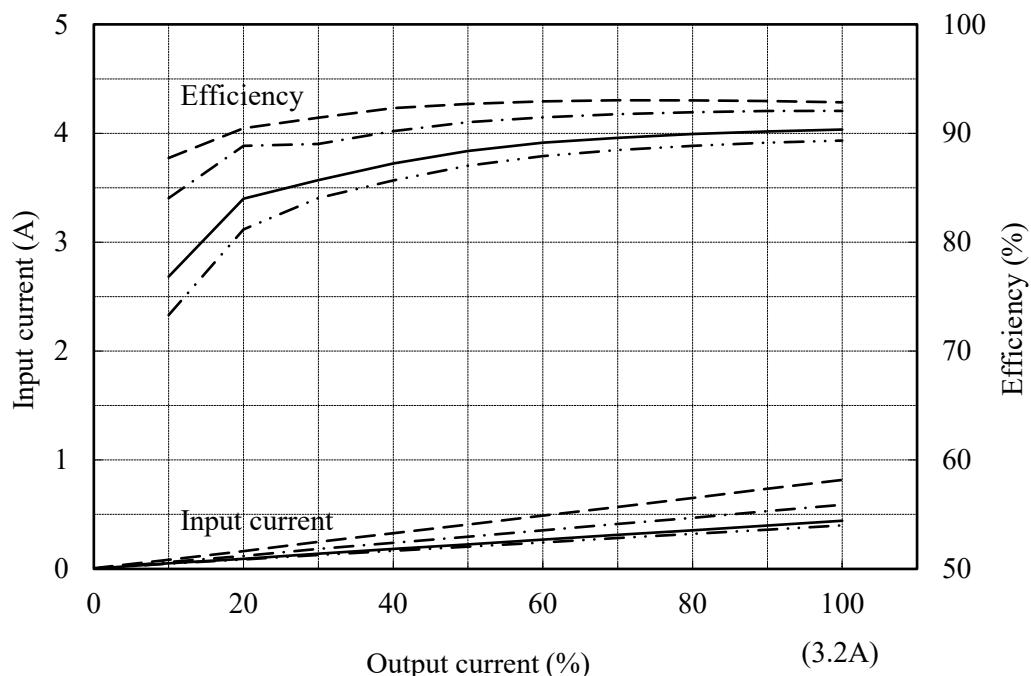


(3) 入力電流、効率 対 出力電流

Input current and Efficiency vs. Output current

Conditions Vin : 200 VDC -----
 : 280 VDC - - - -
 : 380 VDC ——————
 : 425 VDC - · - - -
Tbp : 25 °C

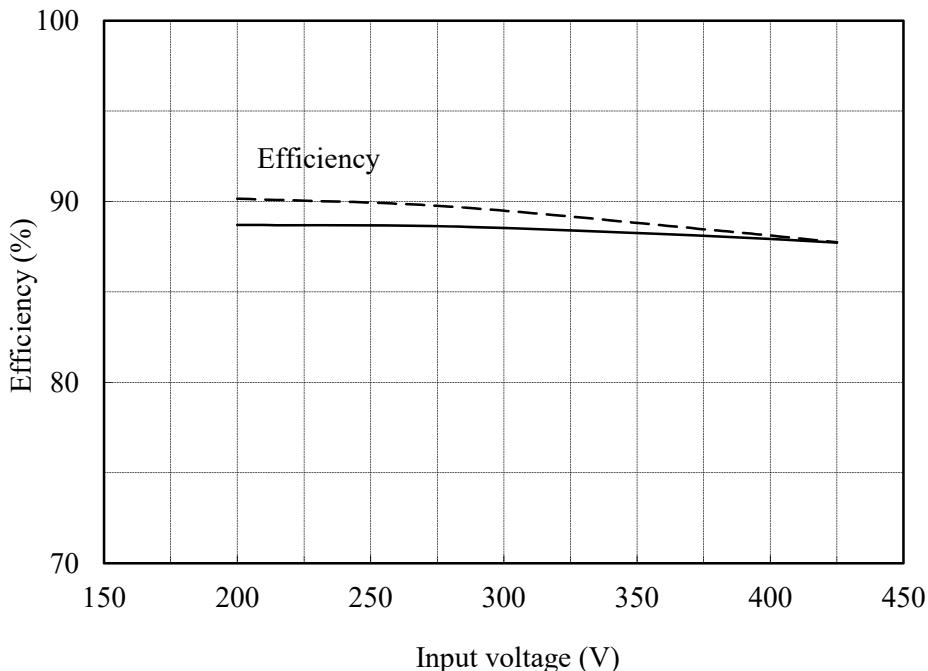
48V



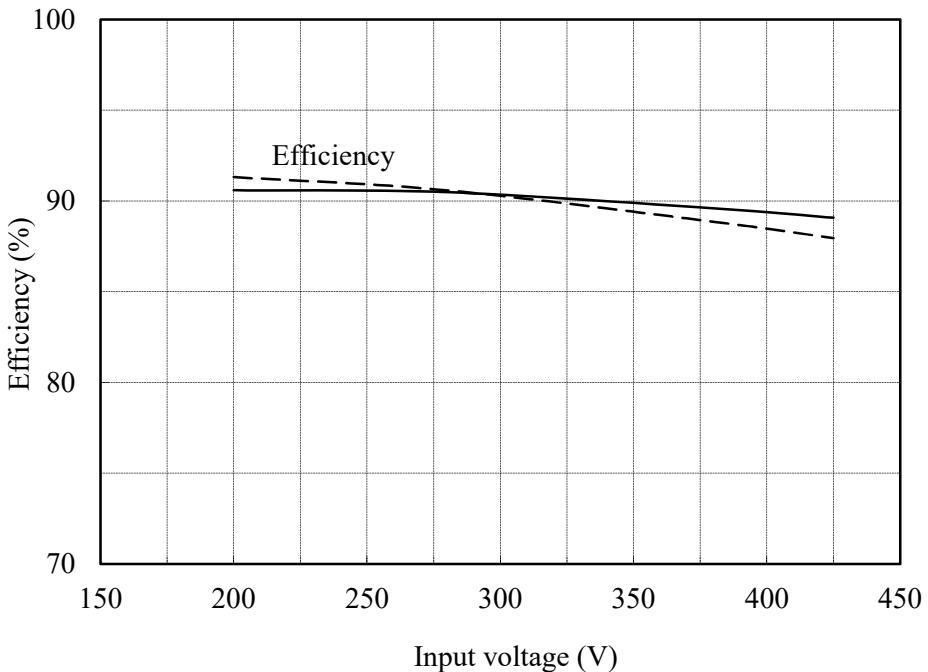
(4) 効率 対 入力電圧
Efficiency vs. Input voltage

Conditions Io : 50 % -----
 : 100 % ---
 Tbp : 25 °C

12V



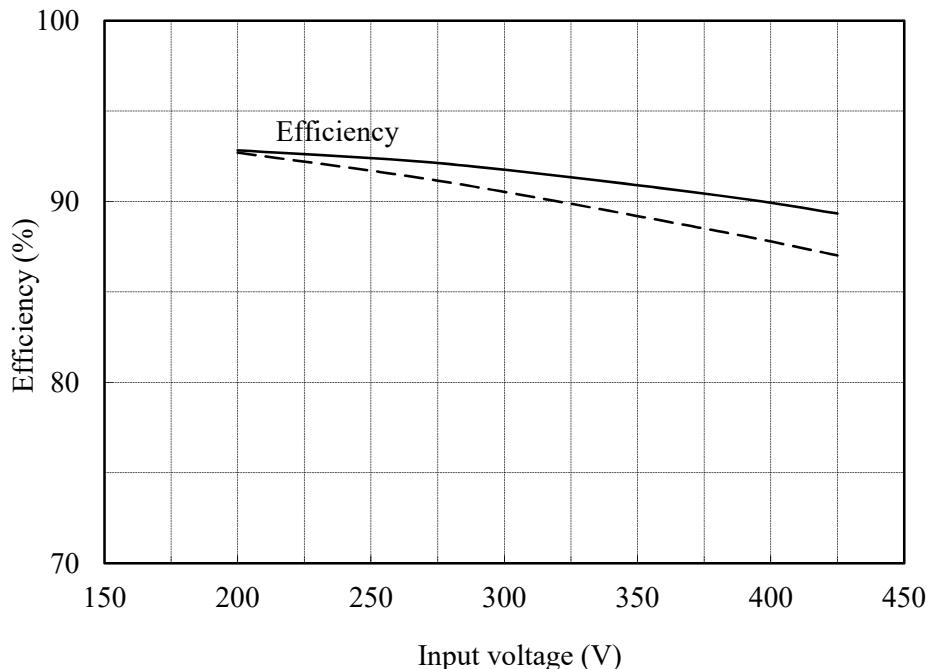
24V



(4) 効率 対 入力電圧
Efficiency vs. Input voltage

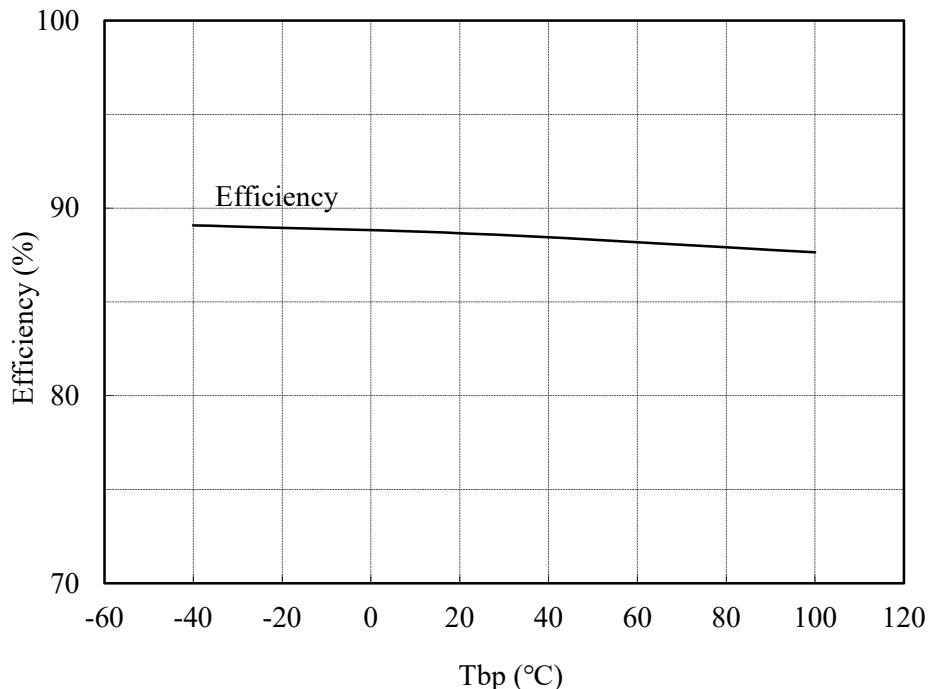
Conditions Io : 50 %
: 100 %
Tbp : 25 °C

48V

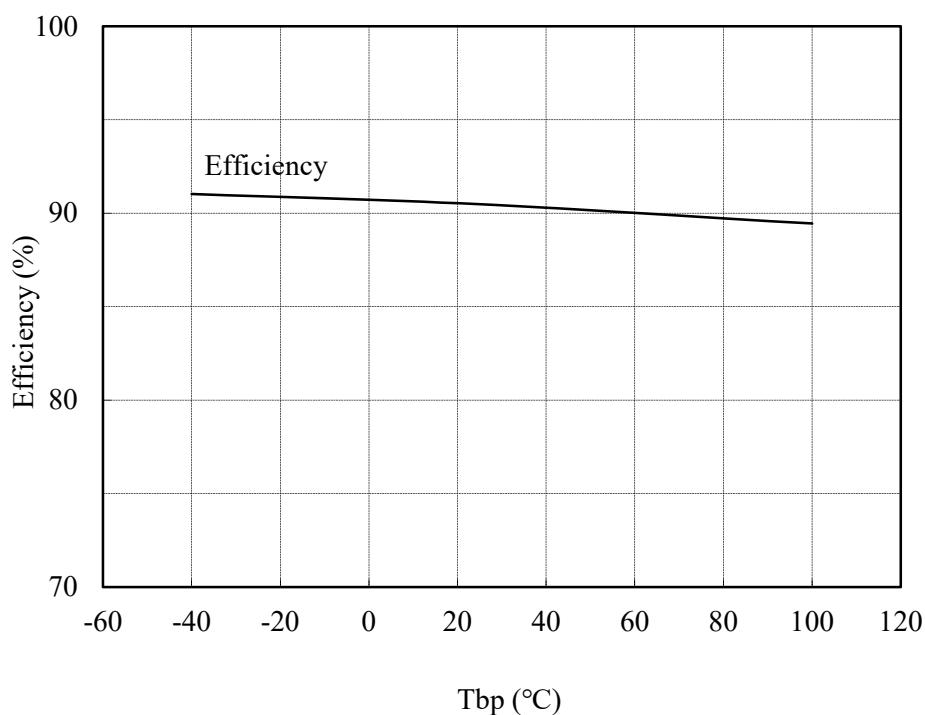


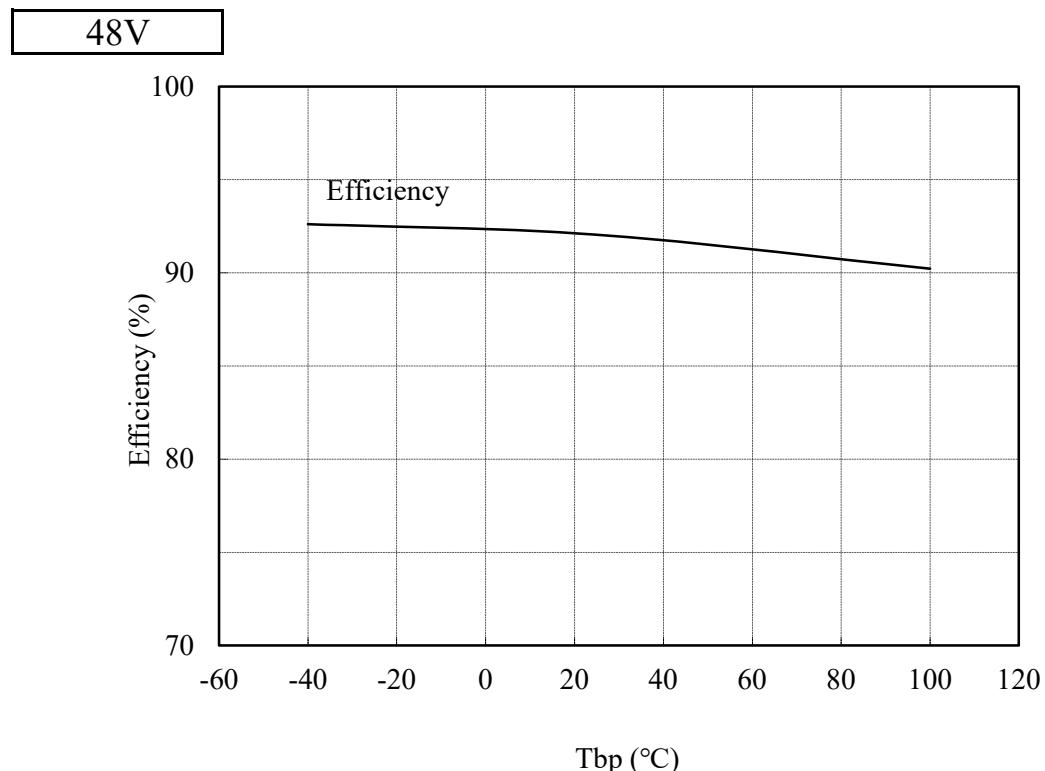
(5) 効率 対 ベースプレート温度
Efficiency vs. Base-plate temperatureConditions Vin : 280 VDC
Io : 100 %

12V



24V



(5) 効率 対 ベースプレート温度
Efficiency vs. Base-plate temperatureConditions Vin : 280 VDC
Io : 100 %

(6) 起動、停止電圧特性

Start and Stop voltage characteristics

出力電圧 対 入力電圧

Output voltage vs. Input voltage

Conditions Io : 100 %

Tbp : 25 °C

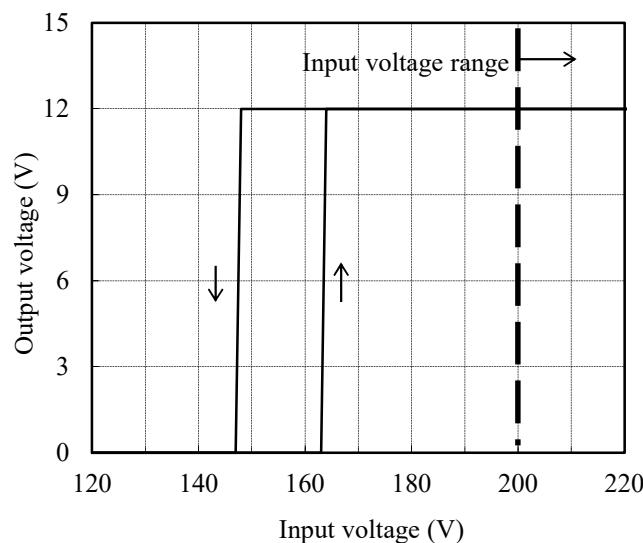
入力電流 対 入力電圧

Input current vs. Input voltage

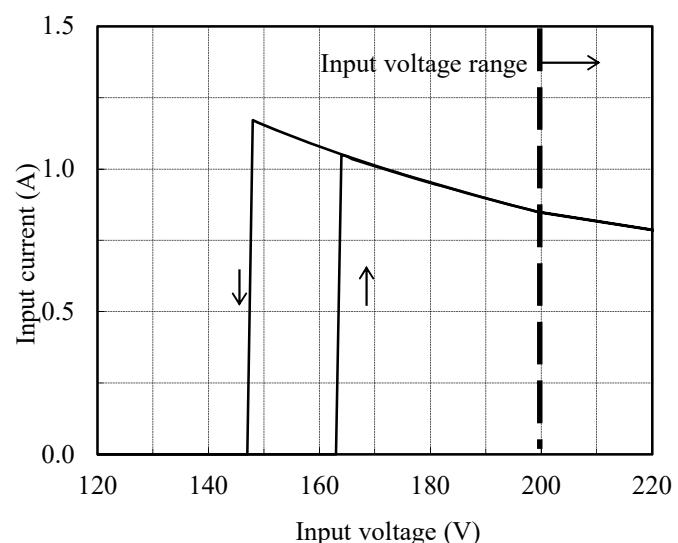
Conditions Io : 100 %

Tbp : 25 °C

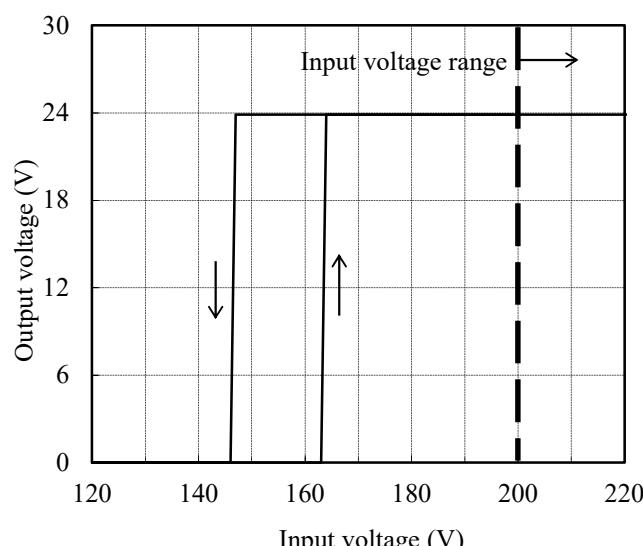
12V



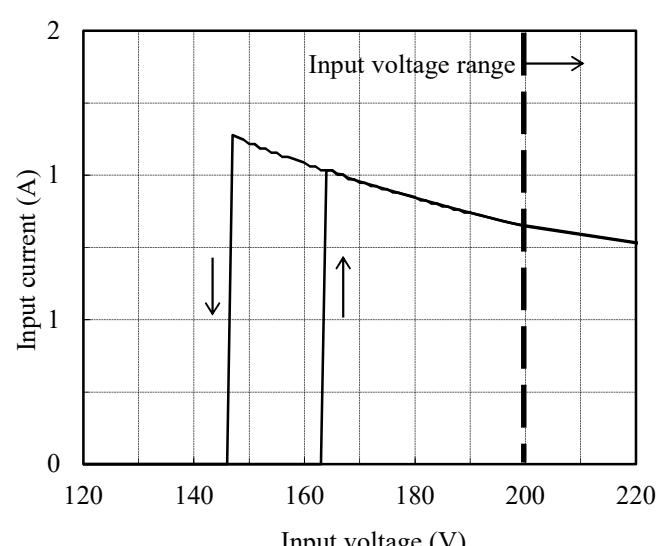
12V



24V



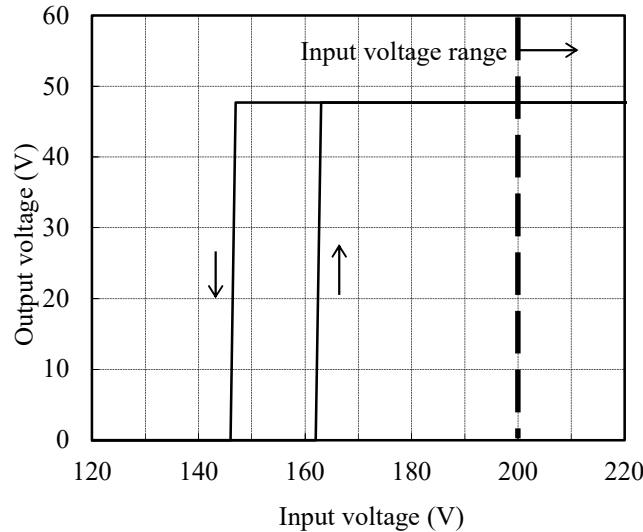
24V



(6) 起動、停止電圧特性
Start and Stop voltage characteristics

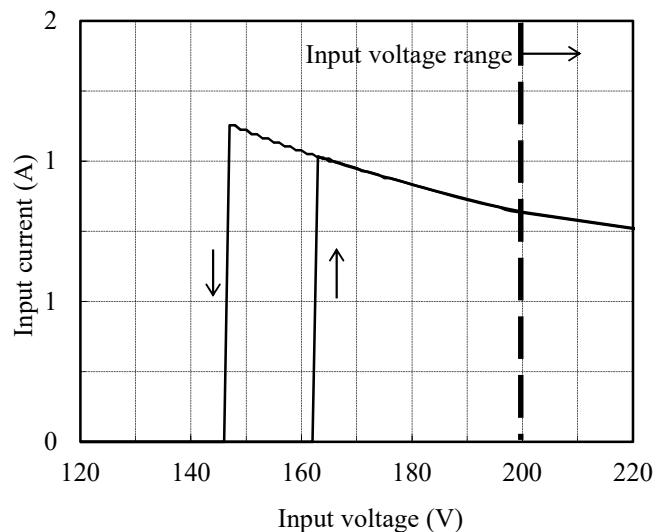
出力電圧 対 入力電圧
Output voltage vs. Input voltage
Conditions Io : 100 %
Tbp : 25 °C

48V



入力電流 対 入力電圧
Input current vs. Input voltage
Conditions Io : 100 %
Tbp : 25 °C

48V

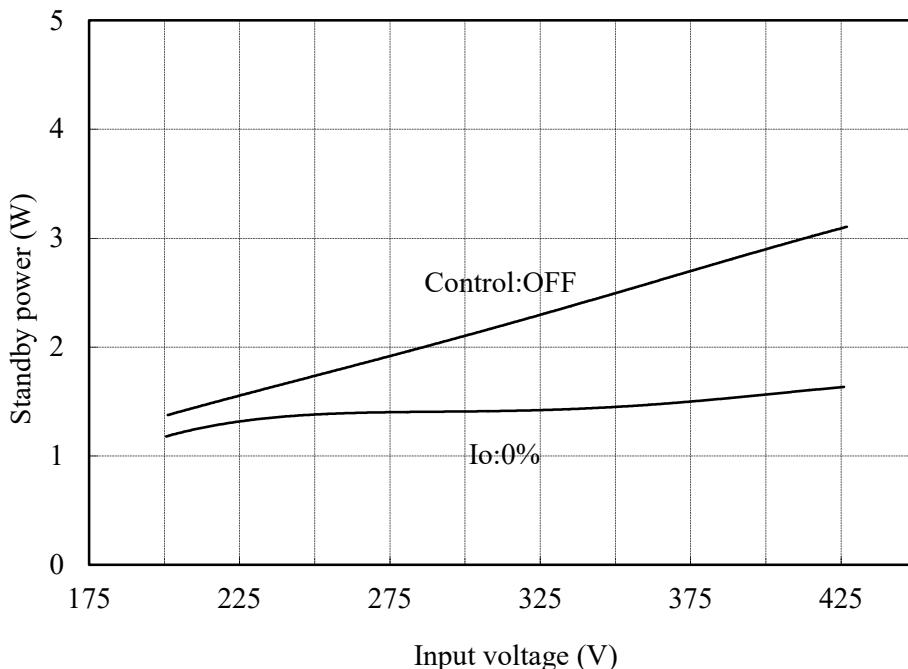


2.2 待機電力特性

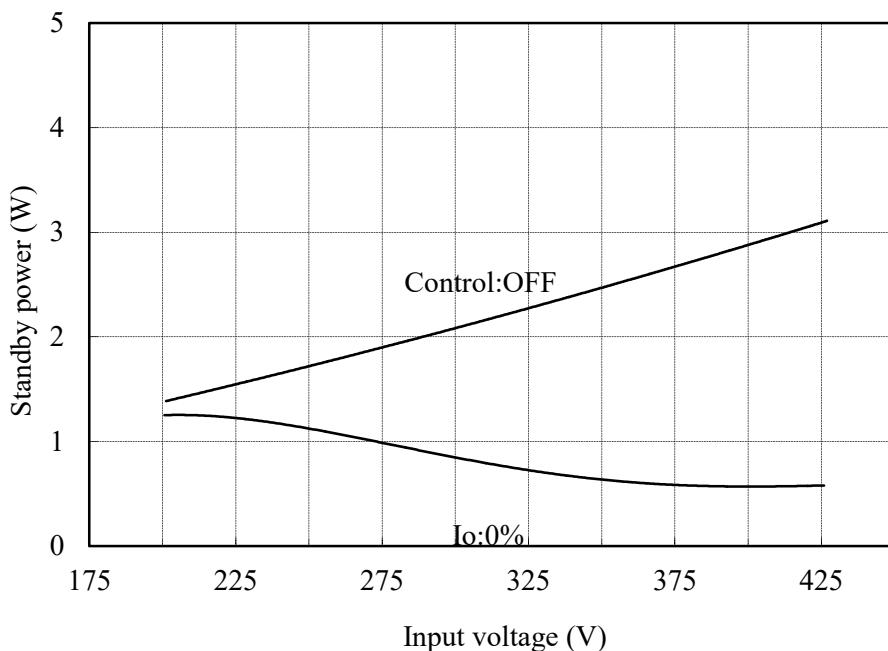
Standby power characteristics

Conditions Tbp : 25 °C

12V



24V

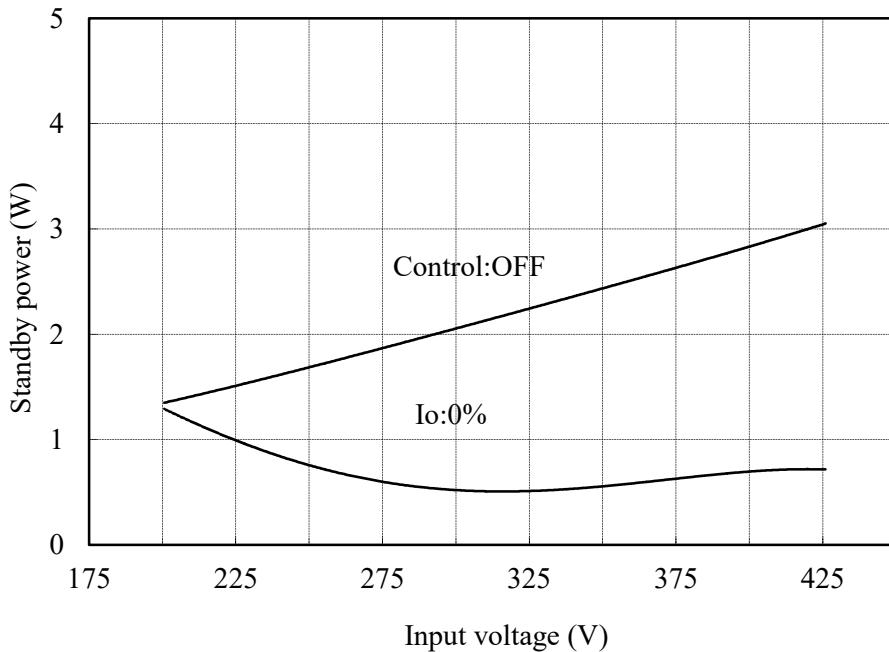


2.2 待機電力特性

Standby power characteristics

Conditions Tbp : 25 °C

48V



2.3 通電ドリフト特性

Warm up voltage drift characteristics

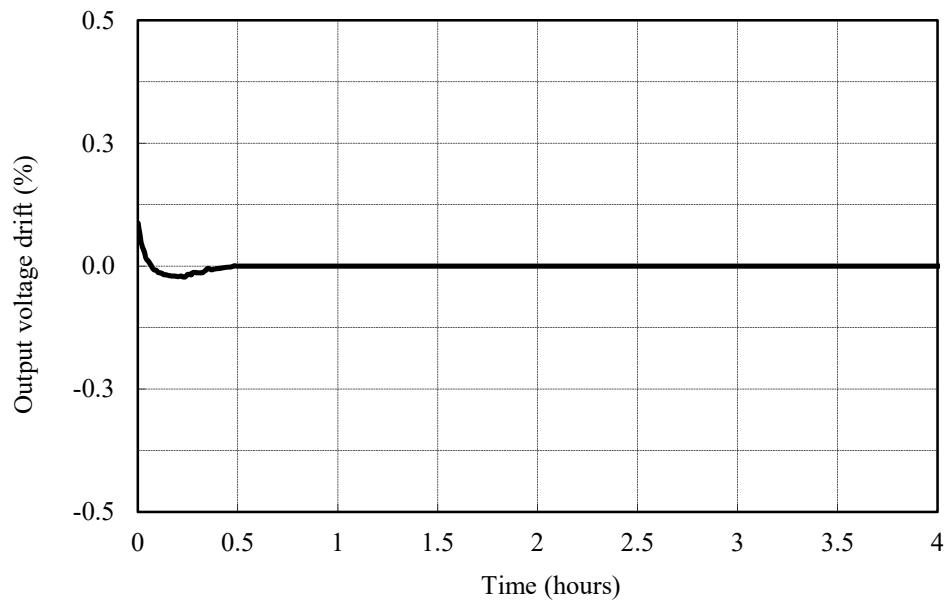
Conditions

Vin : 280 VDC

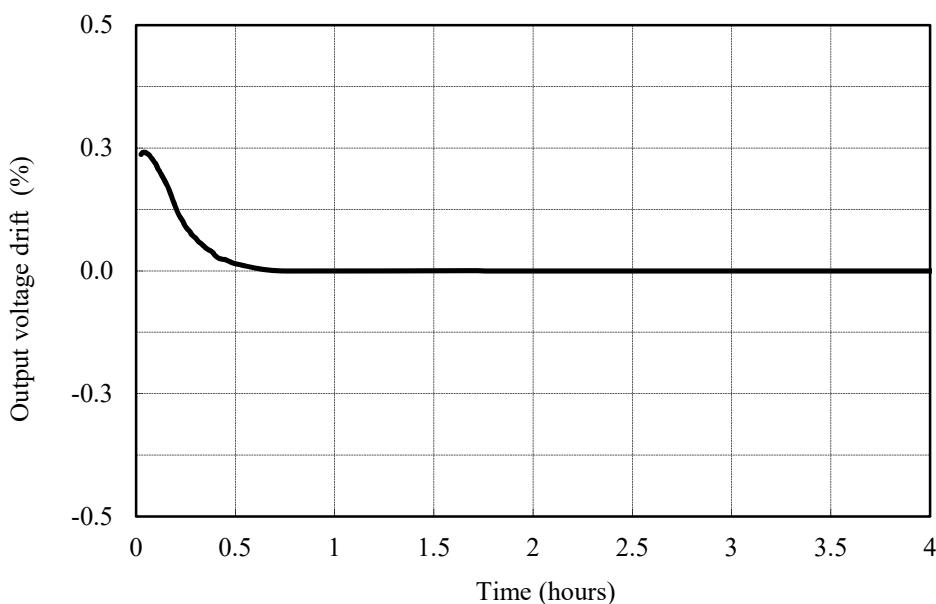
Io : 100 %

Ta : 25 °C

12V



24V



2.3 通電ドリフト特性

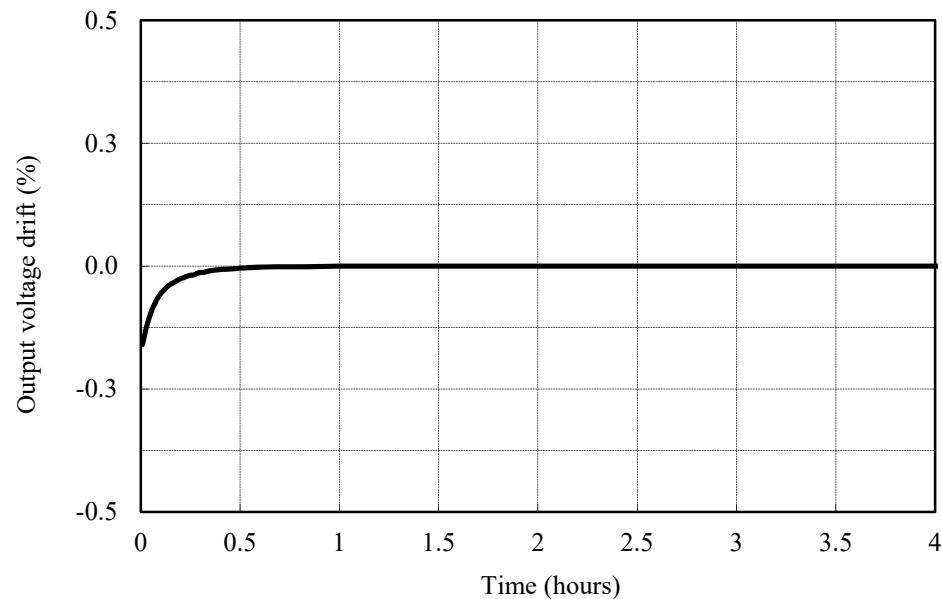
Warm up voltage drift characteristics

Conditions

Vin : 280 VDC

Io : 100 %

Ta : 25 °C

48V

2.4 過電流保護特性

Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

Conditions Vin : 200 VDC -----

: 280 VDC - - - -

: 380 VDC —————

: 425 VDC - · - - -

Tbp : 25 °C

ベースプレート温度依存性

Base-plate temperature dependence

Conditions Vin : 280 VDC -----

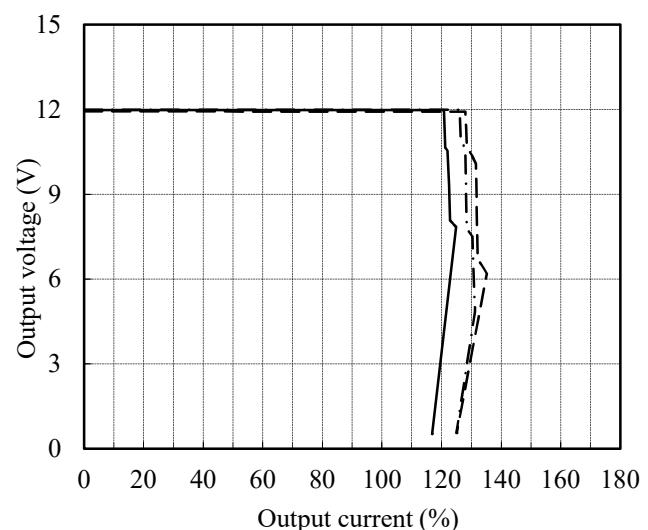
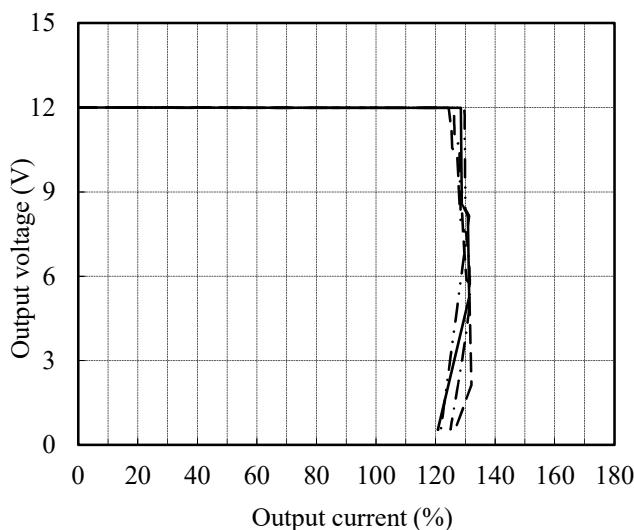
Tbp : -40 °C - - - -

: 25 °C - - - -

: 100 °C —————

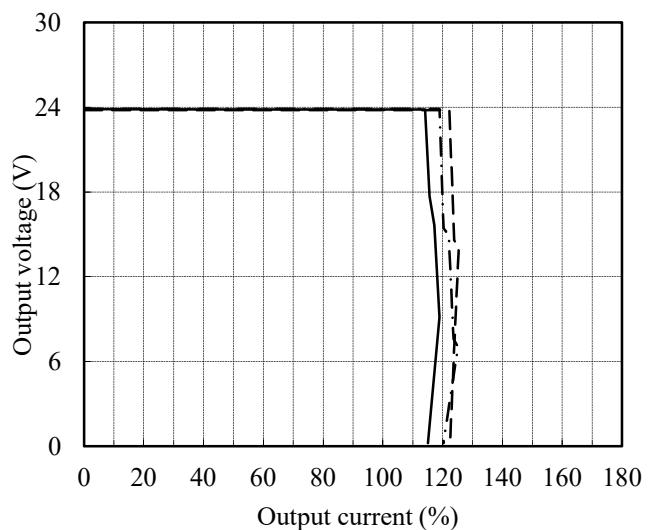
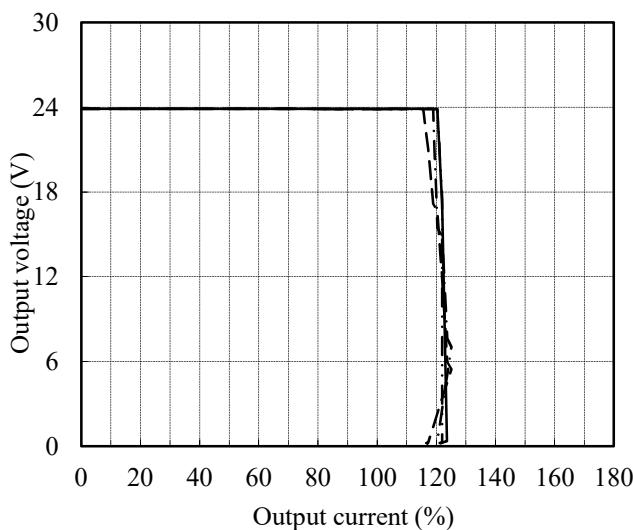
12V

12V



24V

24V



2.4 過電流保護特性

Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

Conditions Vin : 200 VDC -----

: 280 VDC - - - -

: 380 VDC —————

: 425 VDC - · - - -

Tbp : 25 °C

ベースプレート温度依存性

Base-plate temperature dependence

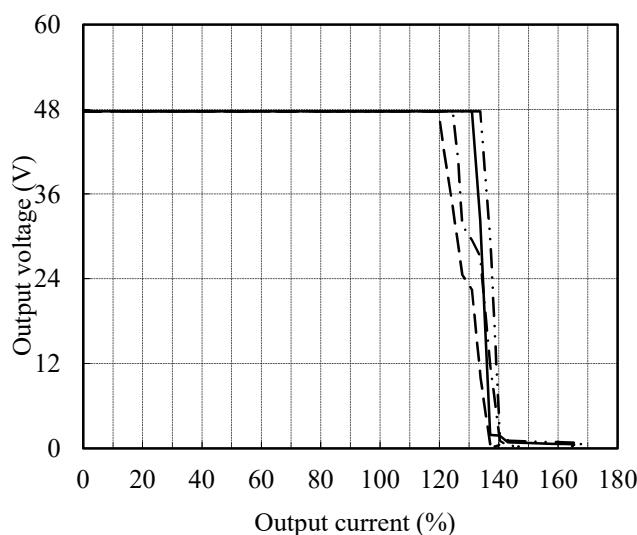
Conditions Vin : 280 VDC

Tbp : -40 °C -----

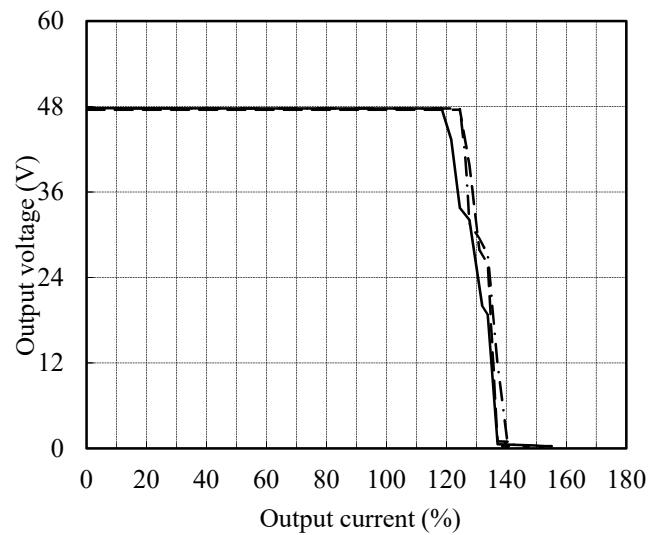
: 25 °C - - - -

: 100 °C —————

48V



48V



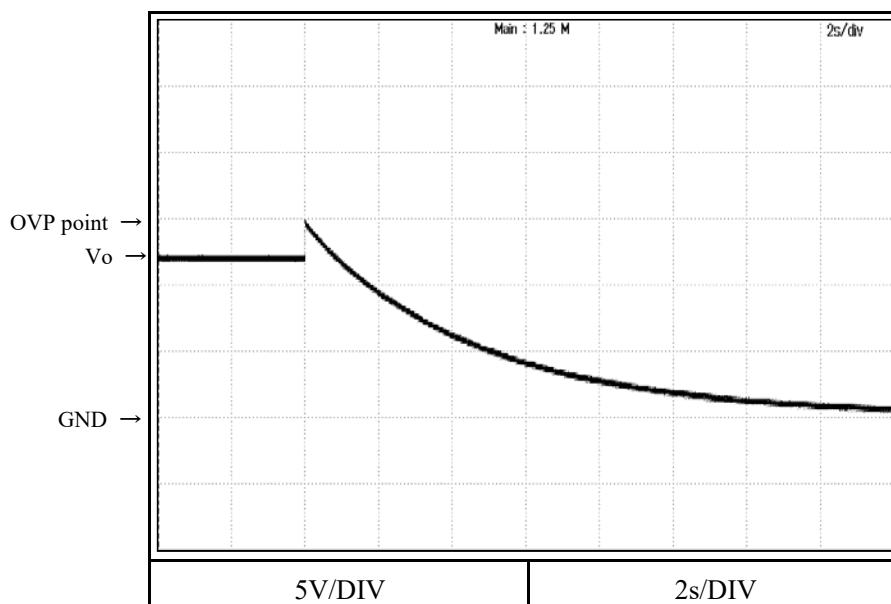
2.5 過電圧保護特性

Over voltage protection (OVP) characteristics

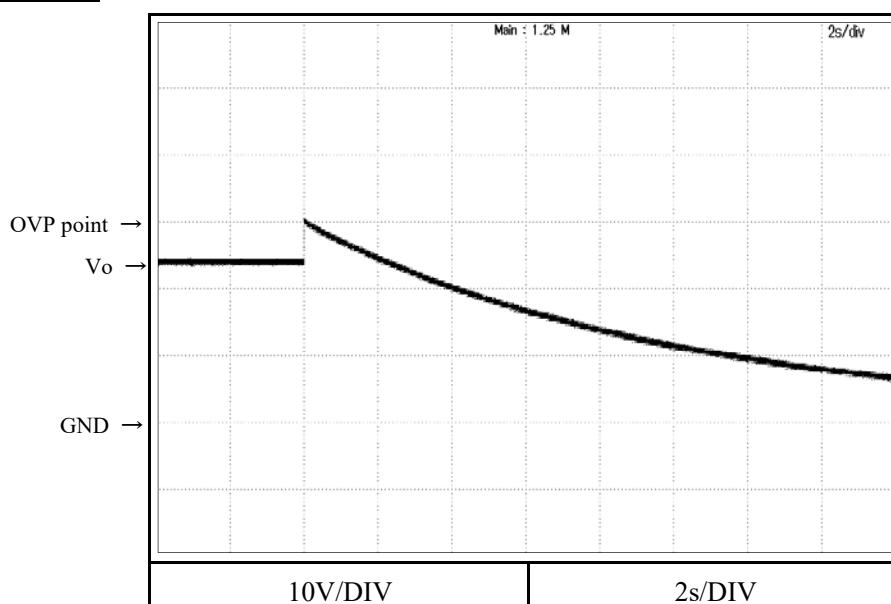
Conditions

Vin : 280 VDC
 Io : 0 %
 Tbp : 25 °C

12V



24V



2.5 過電壓保護特性

Over voltage protection (OVP) characteristics

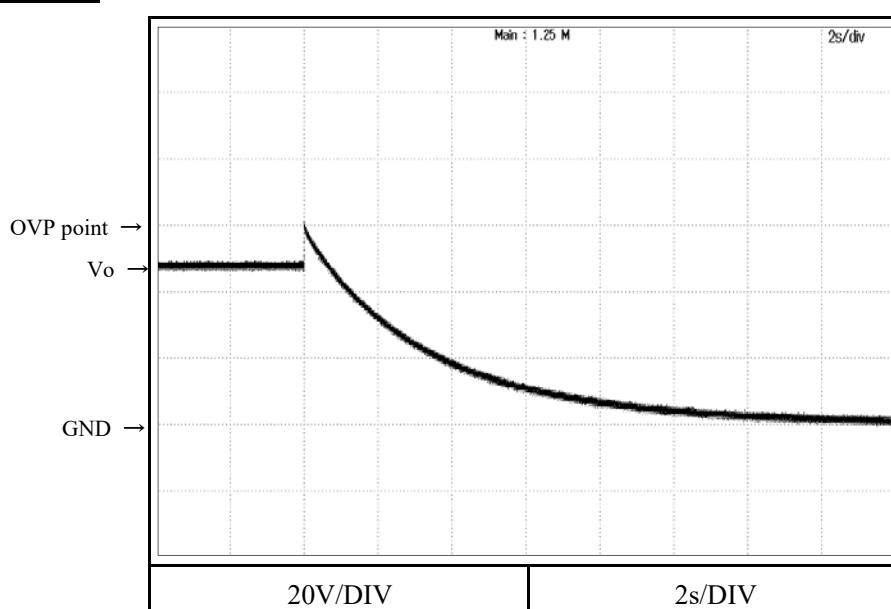
Conditions

Vin : 280 VDC

Io : 0 %

Tbp : 25 °C

48V



2.6 出力立ち上がり、立ち下がり特性

Output rise and fall characteristics

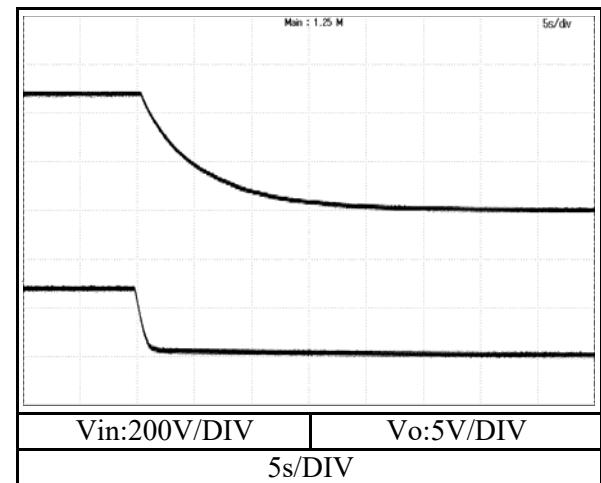
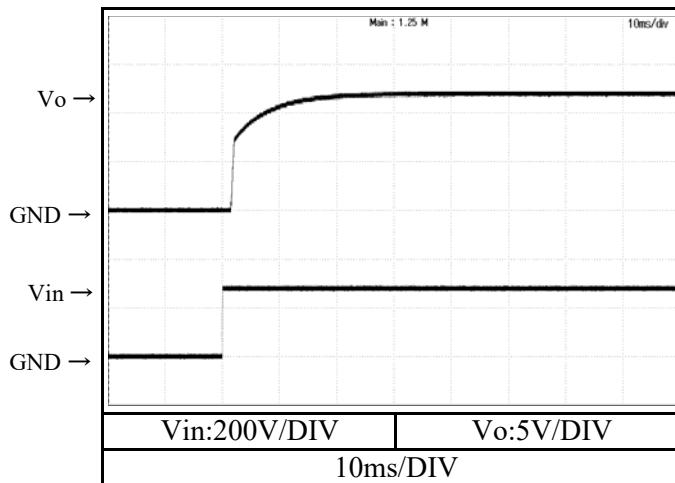
Conditions

Vin : 280 VDC

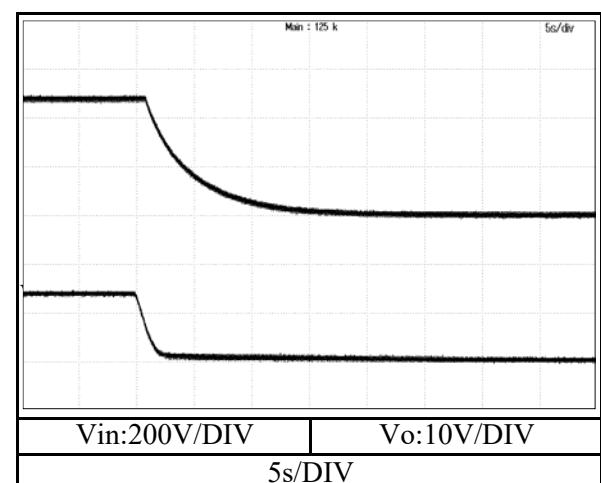
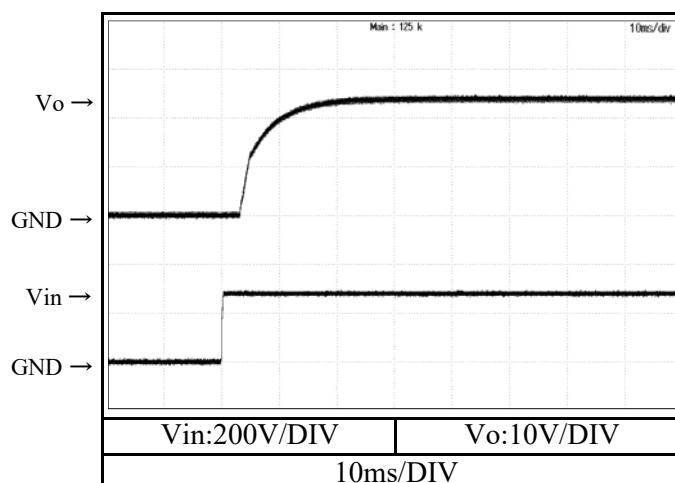
Io : 0 %

Tbp : 25 °C

12V



24V



2.6 出力立ち上がり、立ち下がり特性

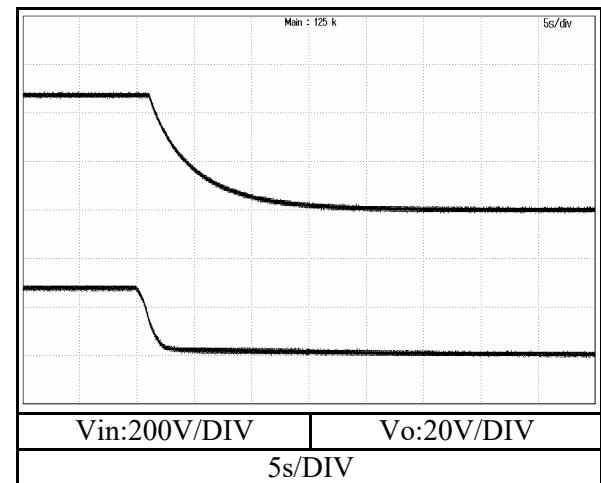
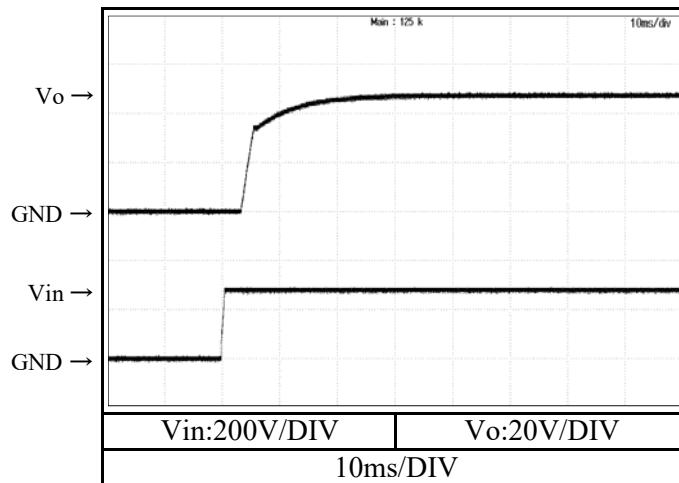
Output rise and fall characteristics

Conditions

Vin : 280 VDC

Io : 0 %

Tbp : 25 °C

48V

2.6 出力立ち上がり、立ち下がり特性

Output rise and fall characteristics

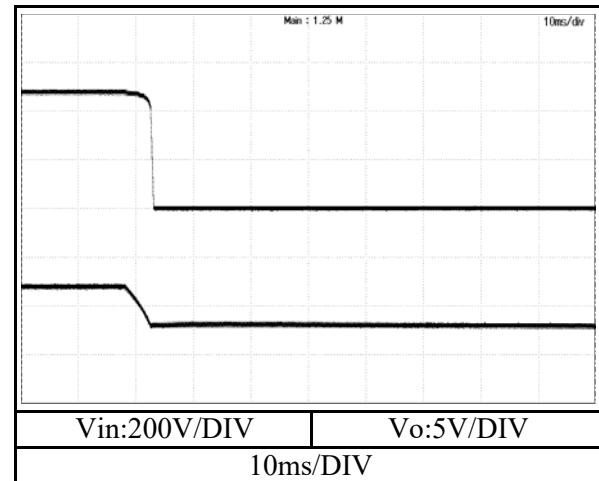
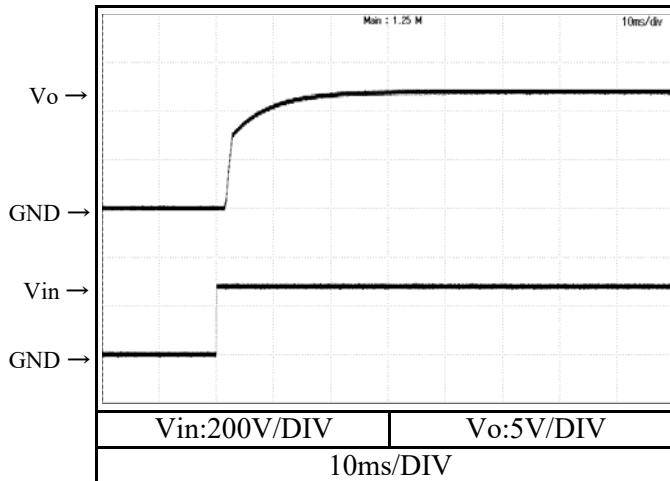
Conditions

Vin : 280 VDC

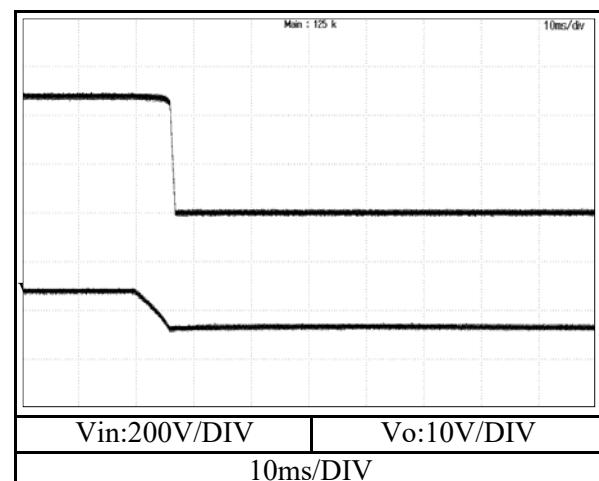
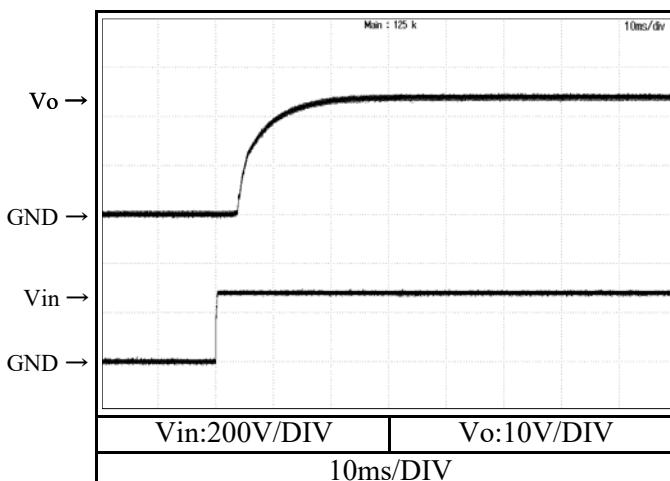
Io : 100 %

Tbp : 25 °C

12V



24V



2.6 出力立ち上がり、立ち下がり特性

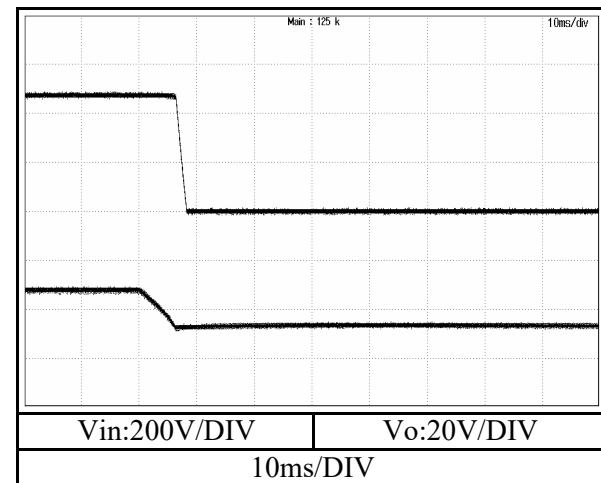
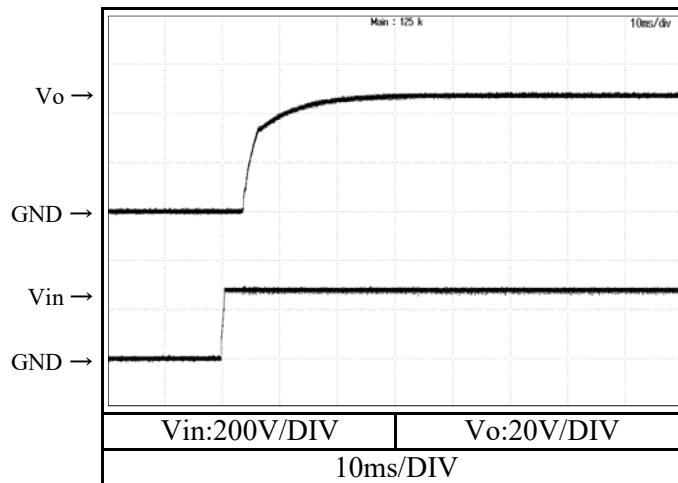
Output rise and fall characteristics

Conditions

Vin : 280 VDC

Io : 100 %

Tbp : 25 °C

48V

2.6 出力立ち上がり、立ち下がり特性 (ON/OFFコントロール時)

Output rise and fall characteristics with ON/OFF CONTROL

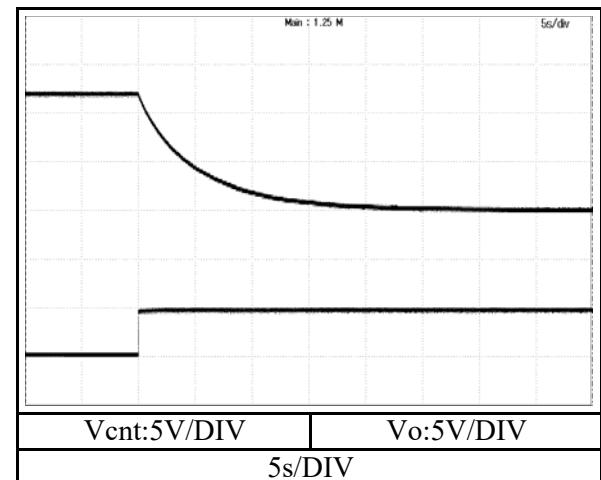
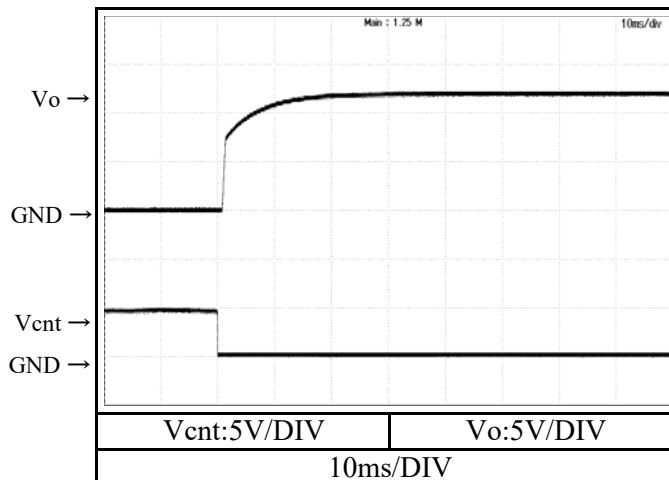
Conditions

Vin : 280 VDC

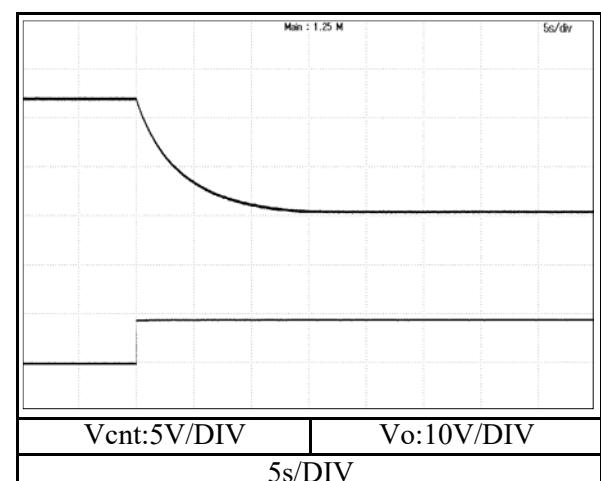
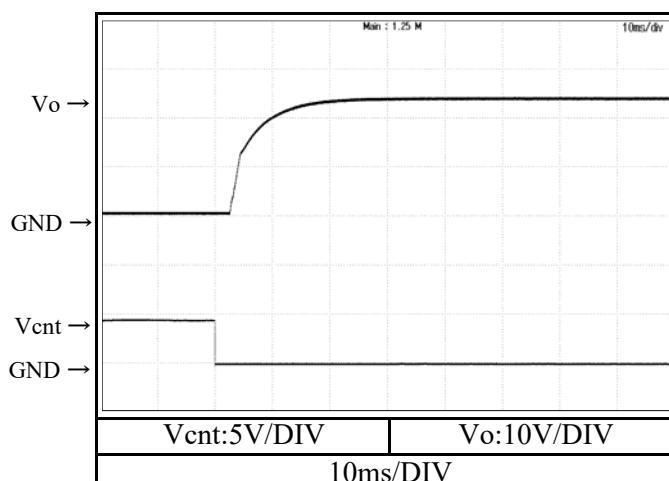
Io : 0 %

Tbp : 25 °C

12V



24V



2.6 出力立ち上がり、立ち下がり特性 (ON/OFFコントロール時)

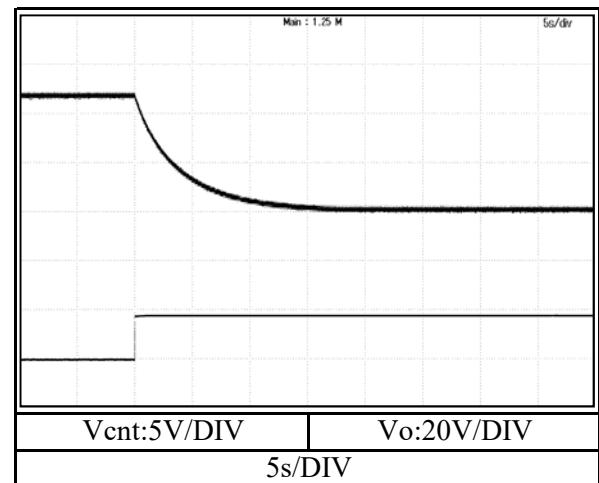
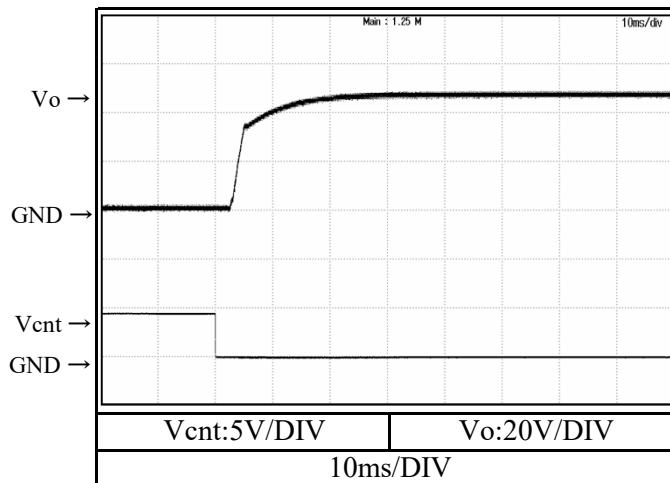
Output rise and fall characteristics with ON/OFF CONTROL

Conditions

Vin : 280 VDC

Io : 0 %

Tbp : 25 °C

48V

2.6 出力立ち上がり、立ち下がり特性 (ON/OFFコントロール時)

Output rise and fall characteristics with ON/OFF CONTROL

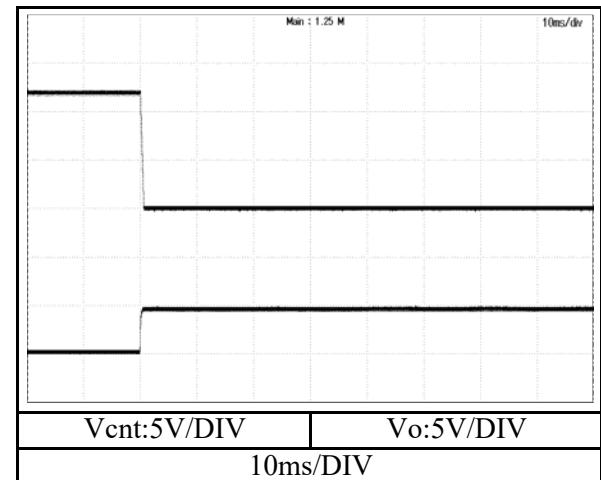
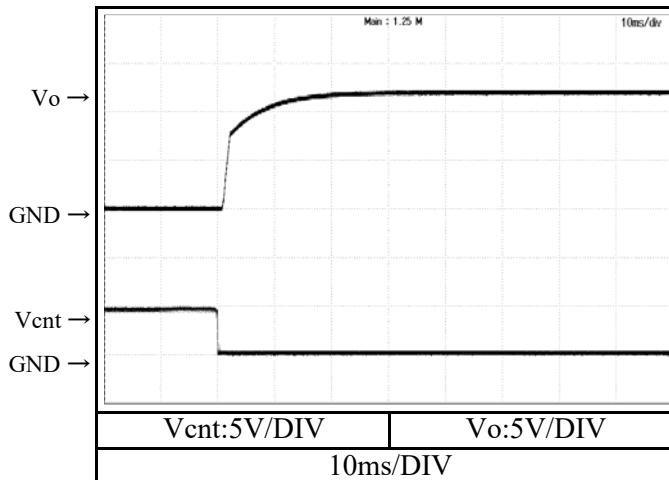
Conditions

Vin : 280 VDC

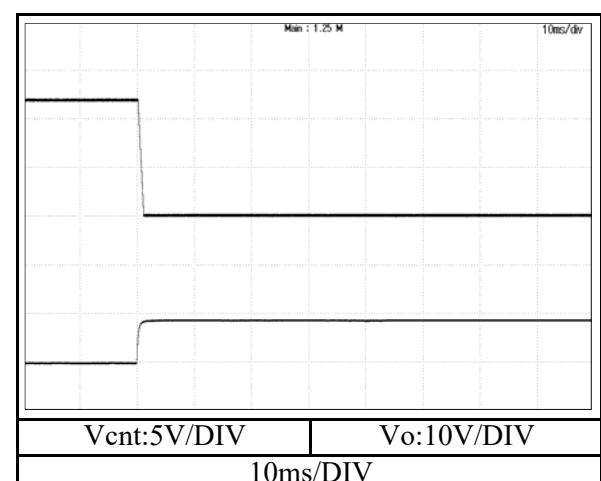
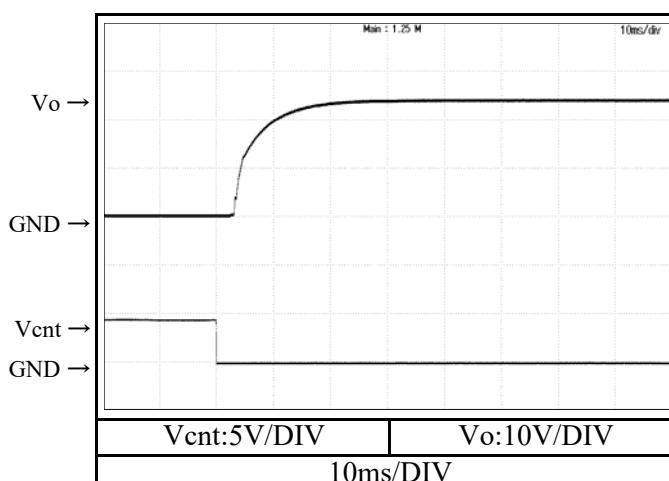
Io : 100 %

Tbp : 25 °C

12V



24V



2.6 出力立ち上がり、立ち下がり特性 (ON/OFFコントロール時)

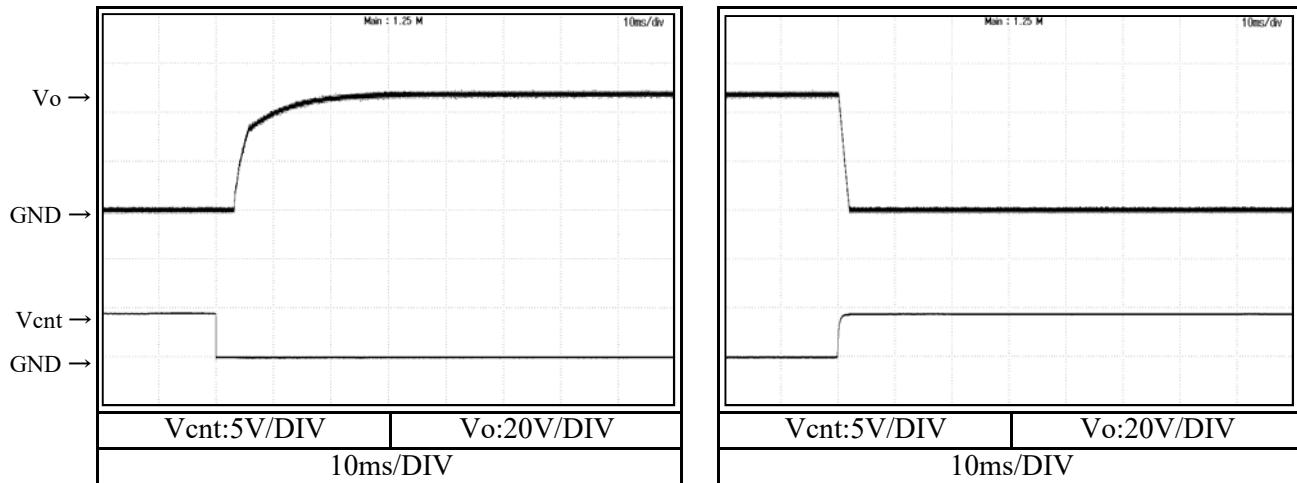
Output rise and fall characteristics with ON/OFF CONTROL

Conditions

Vin : 280 VDC

Io : 100 %

Tbp : 25 °C

48V

2.7 過渡応答（負荷急変）特性

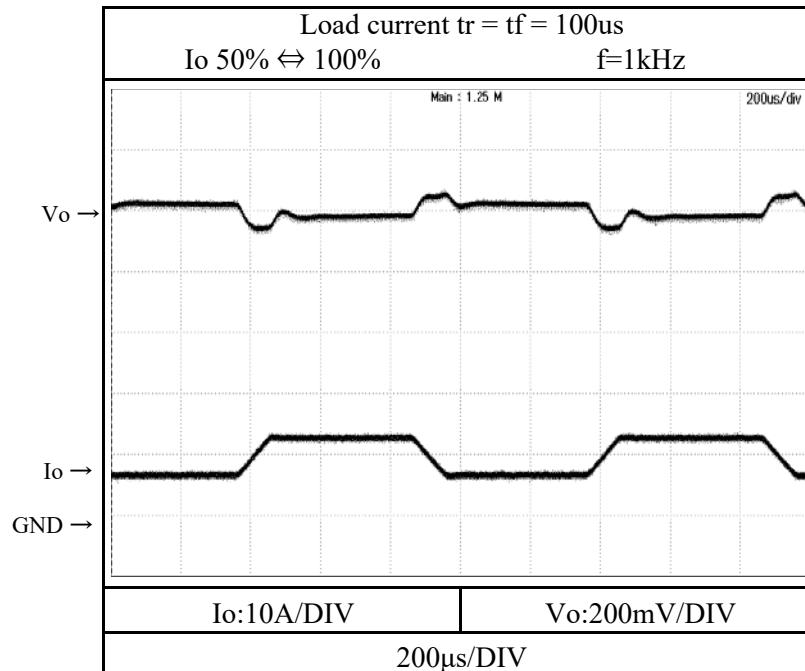
Dynamic load response characteristics

Conditions

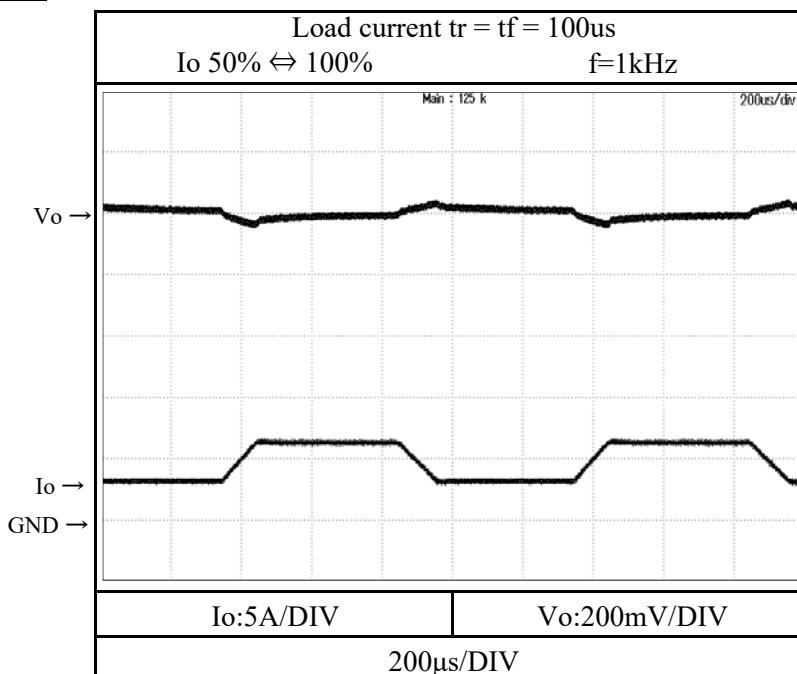
Vin : 280 VDC

Tbp : 25 °C

12V



24V



2.7 過渡応答（負荷急変）特性

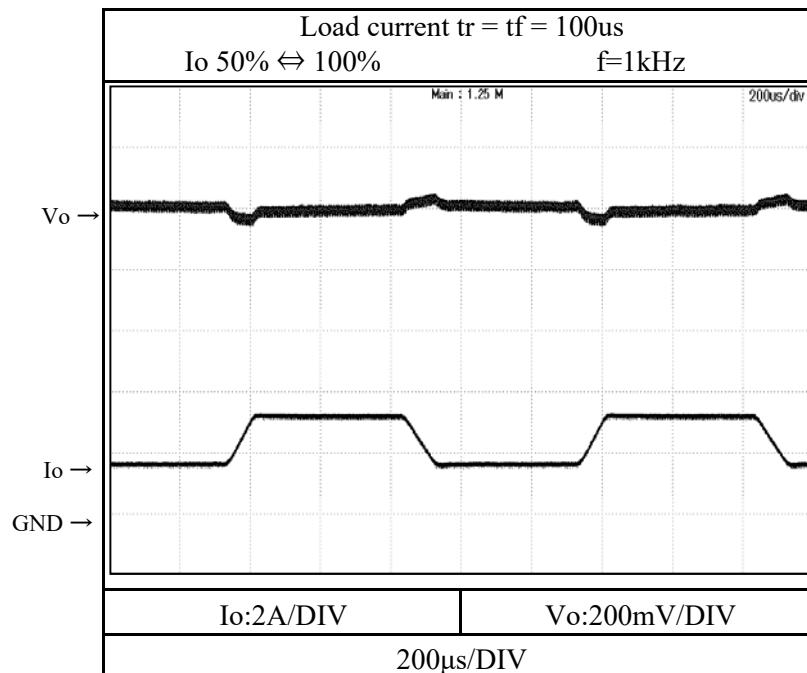
Dynamic load response characteristics

Conditions

Vin : 280 VDC

Tbp : 25 °C

48V



2.8 入力サージ電流（突入電流）特性

Inrush current characteristics

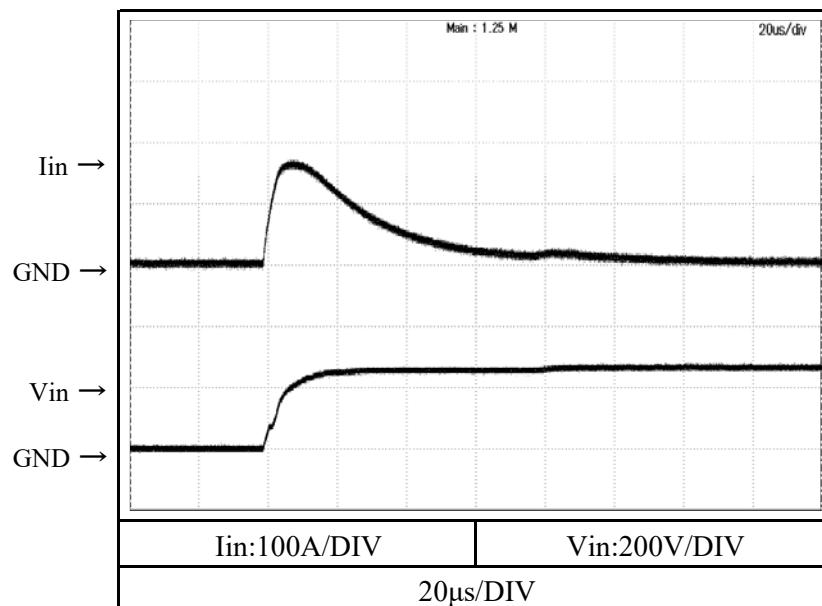
Conditions

Vin : 280 VDC

Io : 100 %

Tbp : 25 °C

48V

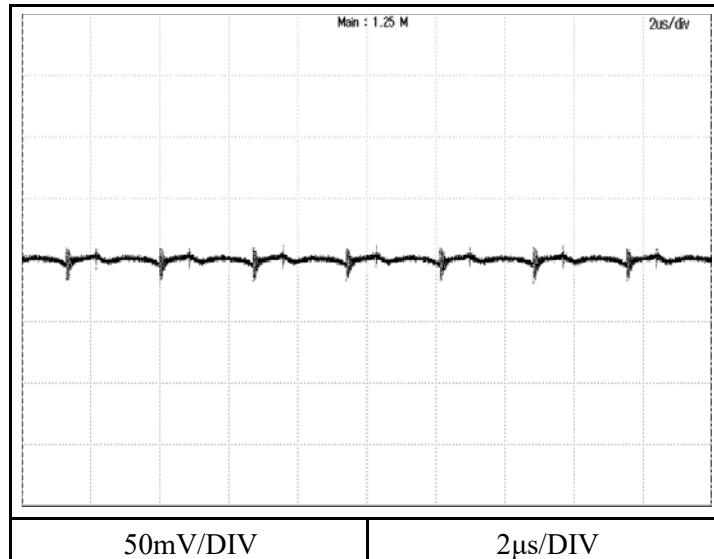


2.9 出力リップル・ノイズ波形
Output ripple and noise waveform

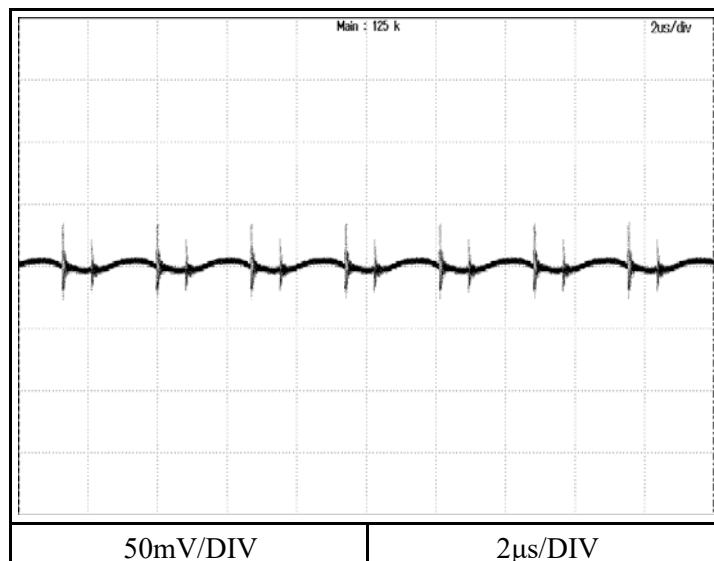
Conditions

Vin : 280 VDC
Io : 100 %
Tbp : 25 °C

12V



24V



2.9 出力リップル・ノイズ波形

Output ripple and noise waveform

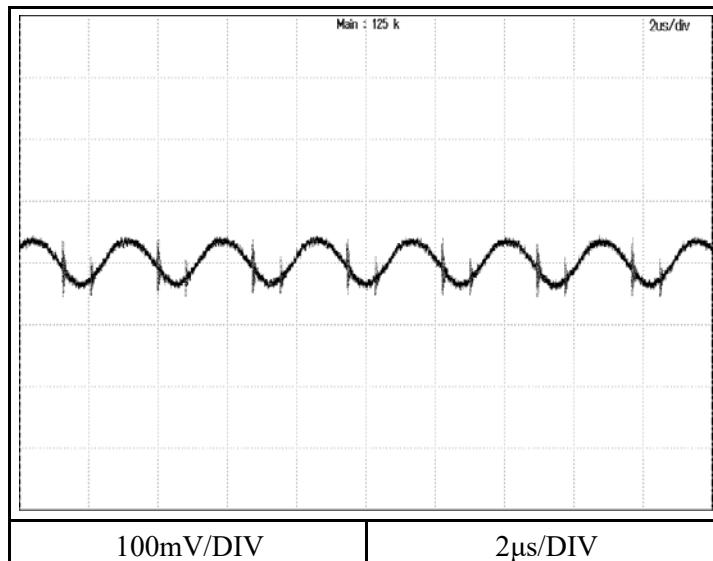
Conditions

Vin : 280 VDC

Io : 100 %

Tbp : 25 °C

48V



2.10 EMI特性

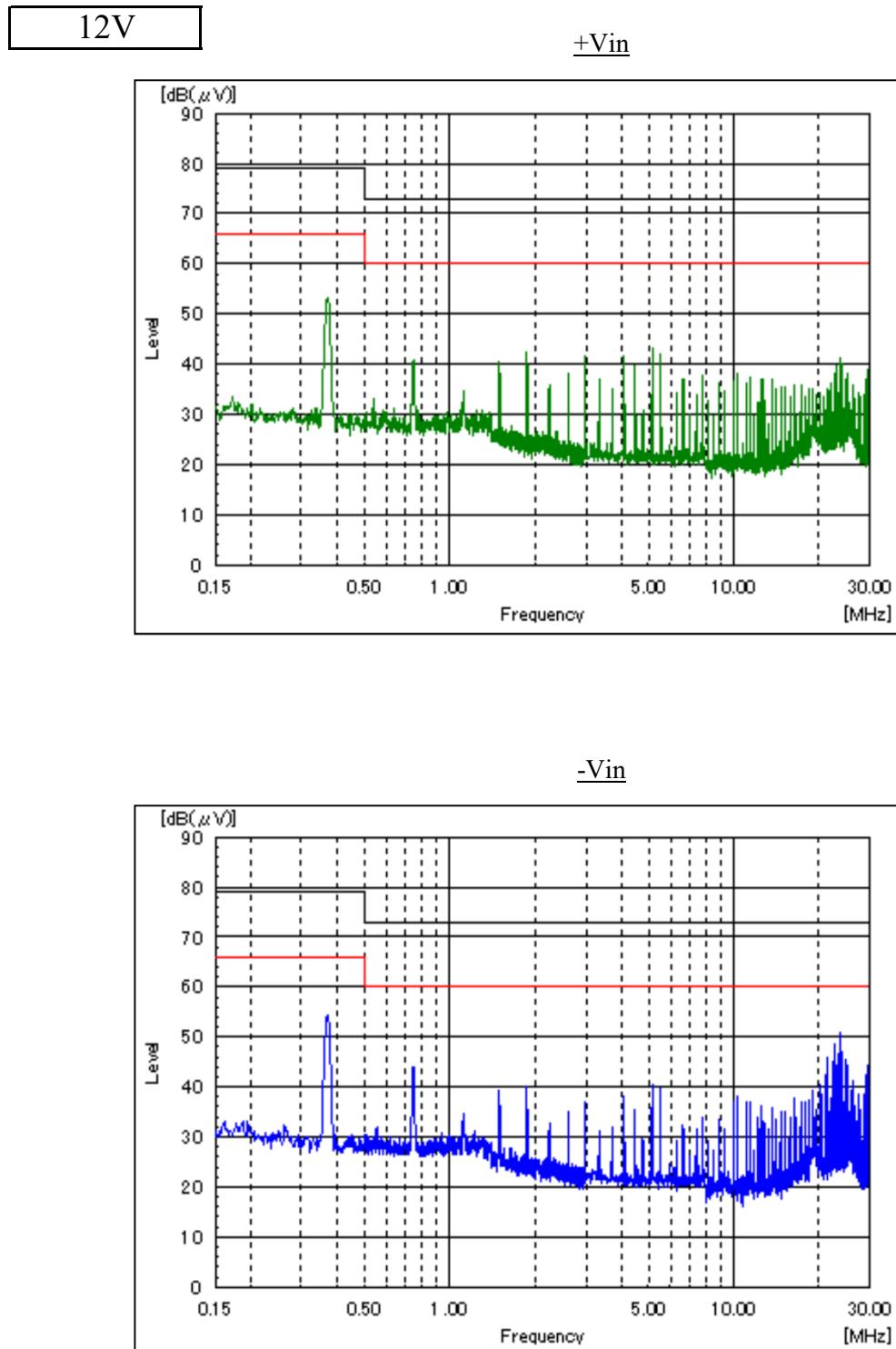
Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ)

Conducted Emission Noise

Conditions

Vin : 280 VDC
 Io : 100 %
 Tbp : 25 °C



EN55011-A, EN55032-A, FCC Part.15 Subpart.B ClassAの限界値は、VCCI ClassAの限界値と同じ
 Limit of EN55011-A, EN55032-A and FCC Part.15 Subpart.B ClassA are same as its VCCI ClassA.

2.10 EMI特性

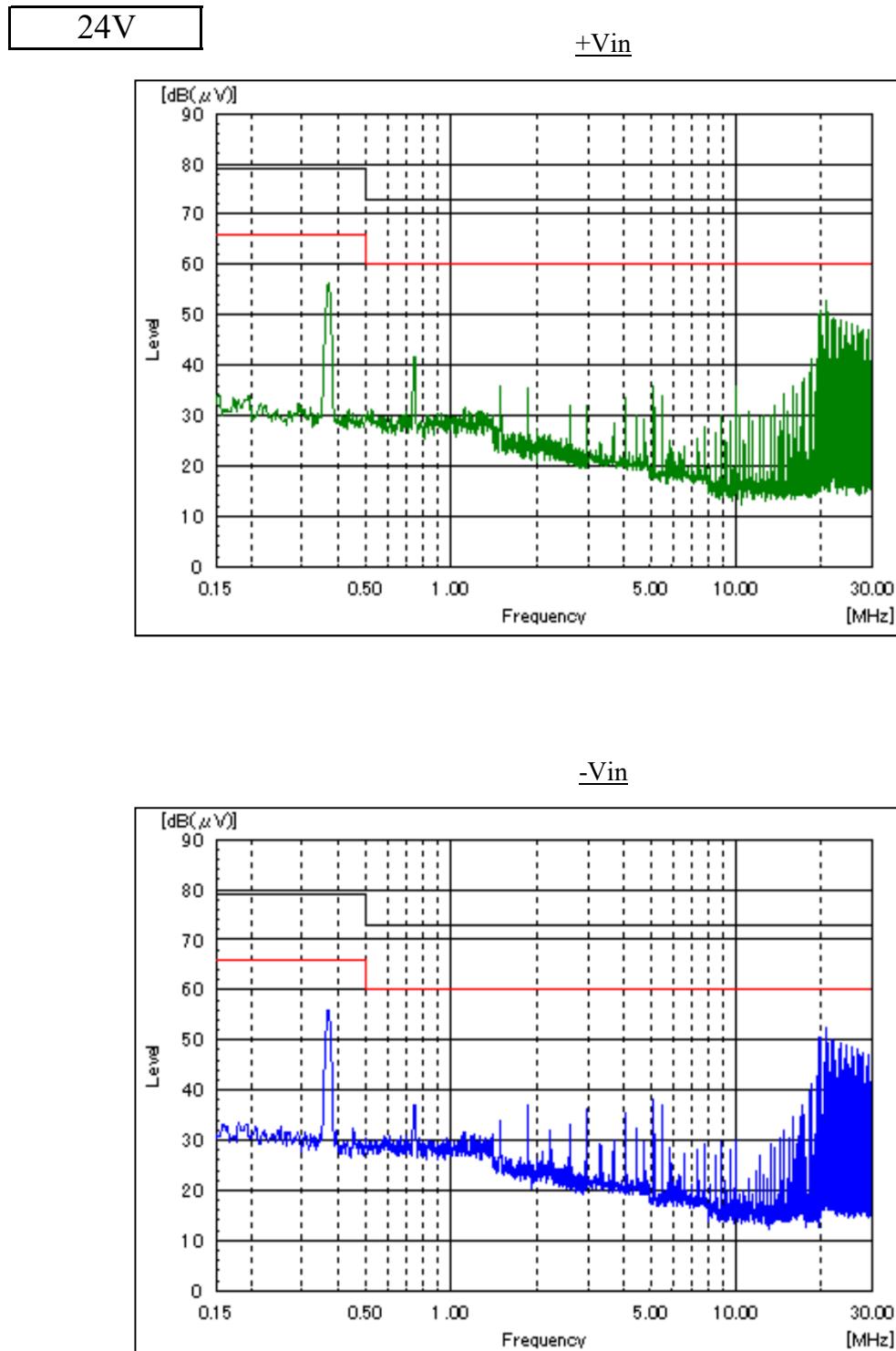
Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ)

Conducted Emission Noise

Conditions

Vin : 280 VDC
 Io : 100 %
 Tbp : 25 °C



EN55011-A, EN55032-A, FCC Part.15 Subpart.B ClassAの限界値は、VCCI ClassAの限界値と同じ
 Limit of EN55011-A, EN55032-A and FCC Part.15 Subpart.B ClassA are same as its VCCI ClassA.

2.10 EMI特性

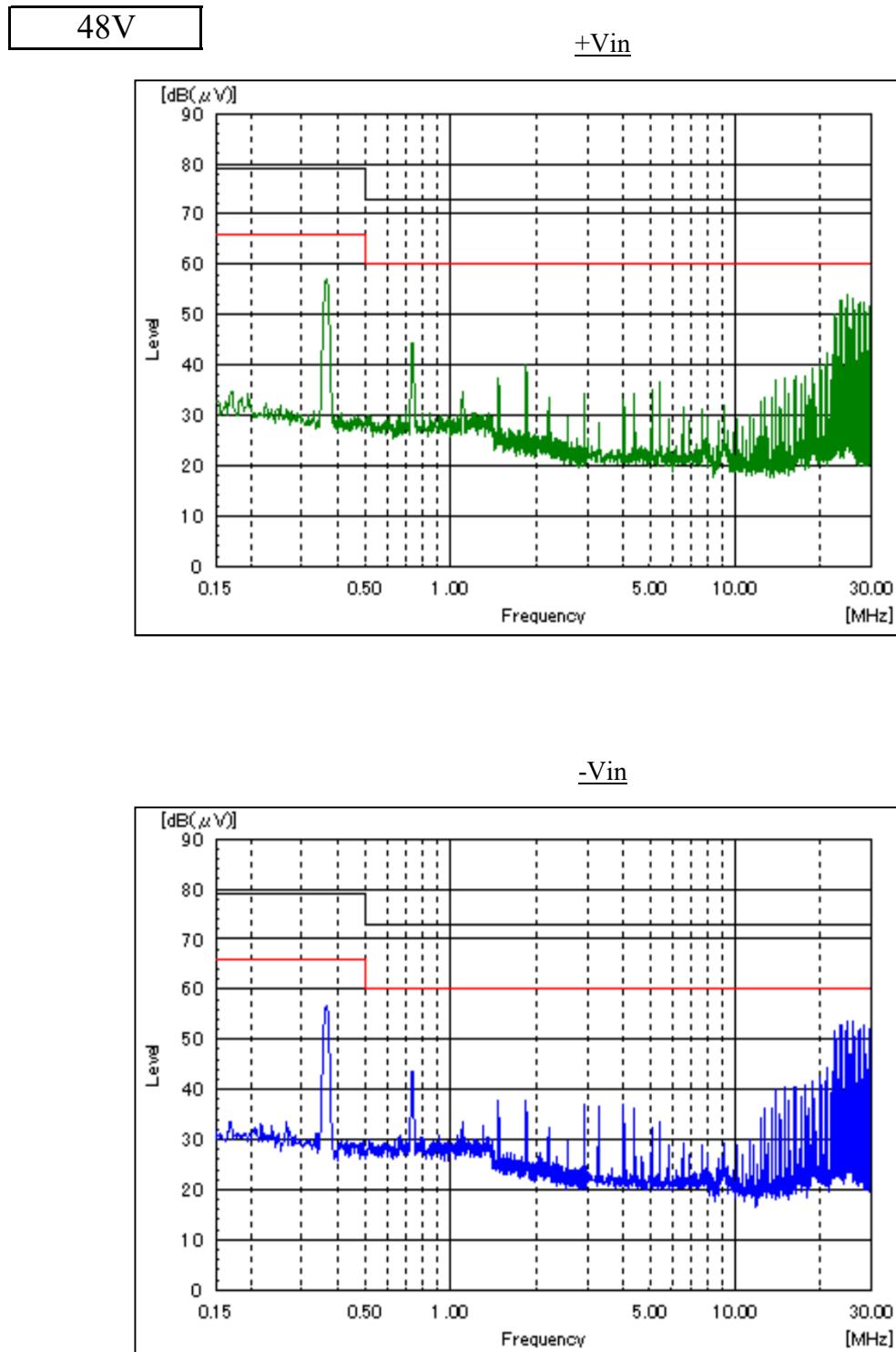
Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ)

Conducted Emission Noise

Conditions

Vin : 280 VDC
 Io : 100 %
 Tbp : 25 °C



EN55011-A, EN55032-A, FCC Part.15 Subpart.B ClassAの限界値は、VCCI ClassAの限界値と同じ
 Limit of EN55011-A, EN55032-A and FCC Part.15 Subpart.B ClassA are same as its VCCI ClassA.

2.10 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

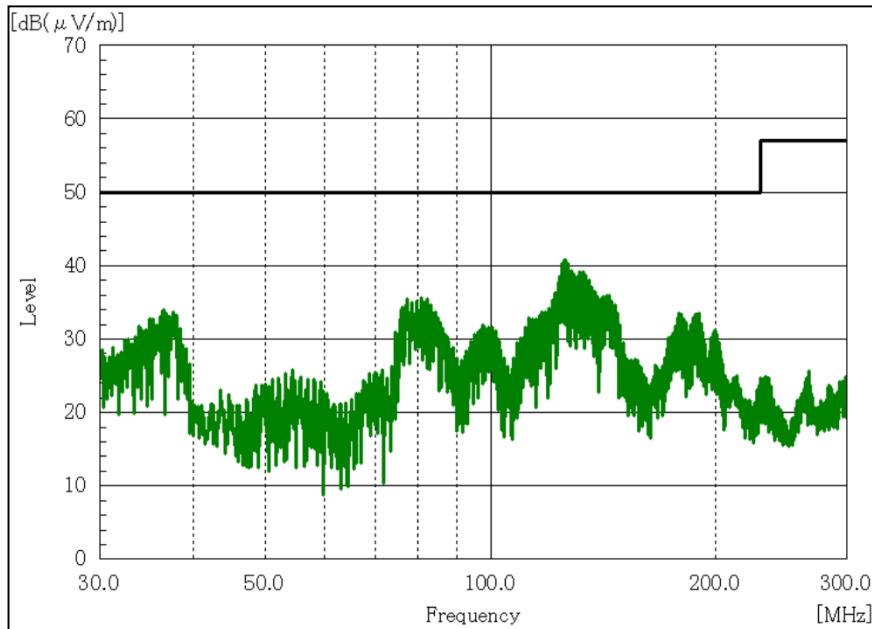
Conditions

Vin : 280 VDC

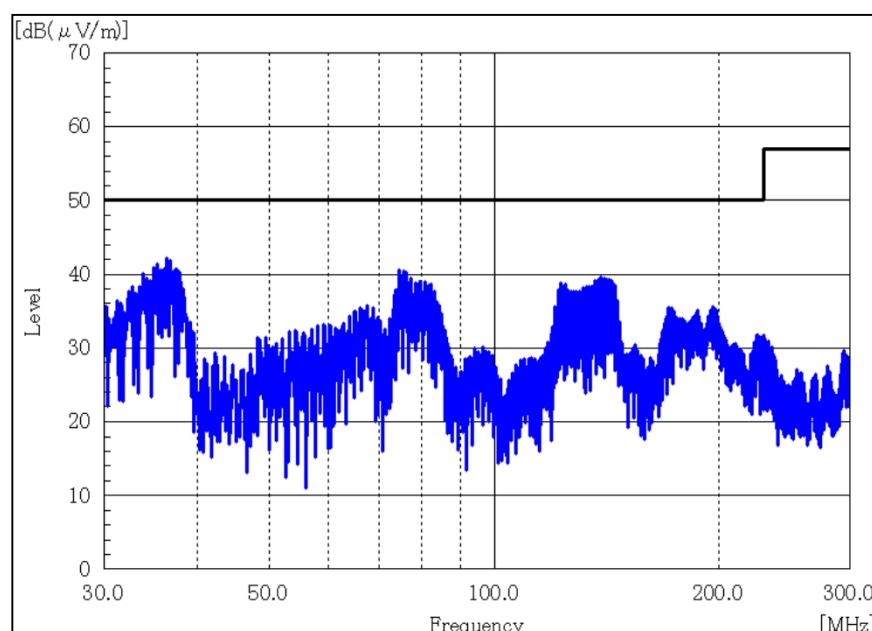
Io : 100 %

Tbp : 25 °C

12V

HORIZONTAL

← VCCI classA
QP Limit
(Distance: 3m)

VERTICAL

← VCCI classA
QP Limit
(Distance: 3m)

EN55011-A, EN55032-Aの限界値は、VCCI ClassAの限界値と同じ

Limit of EN55011-A, EN55032-A are same as its VCCI ClassA.

2.10 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

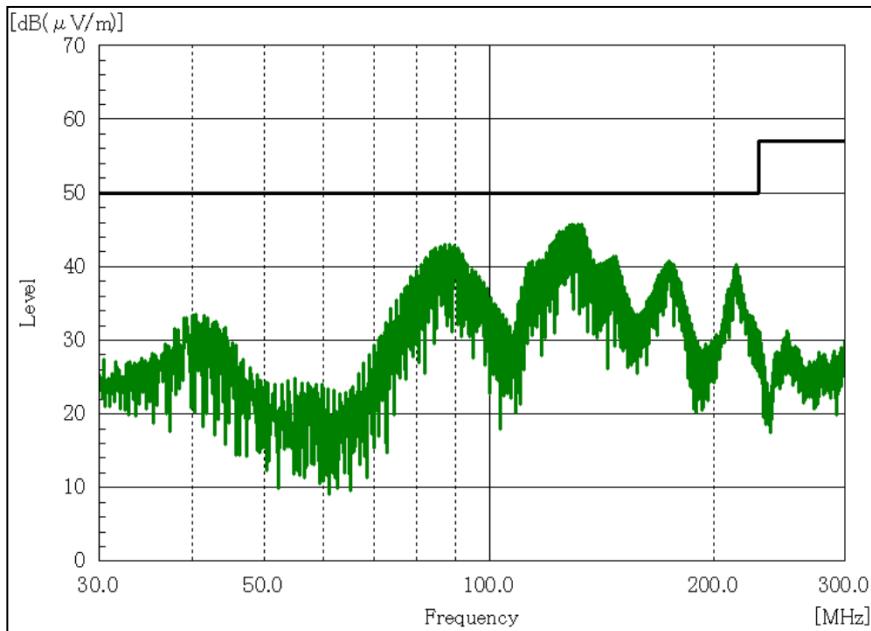
Conditions

Vin : 280 VDC

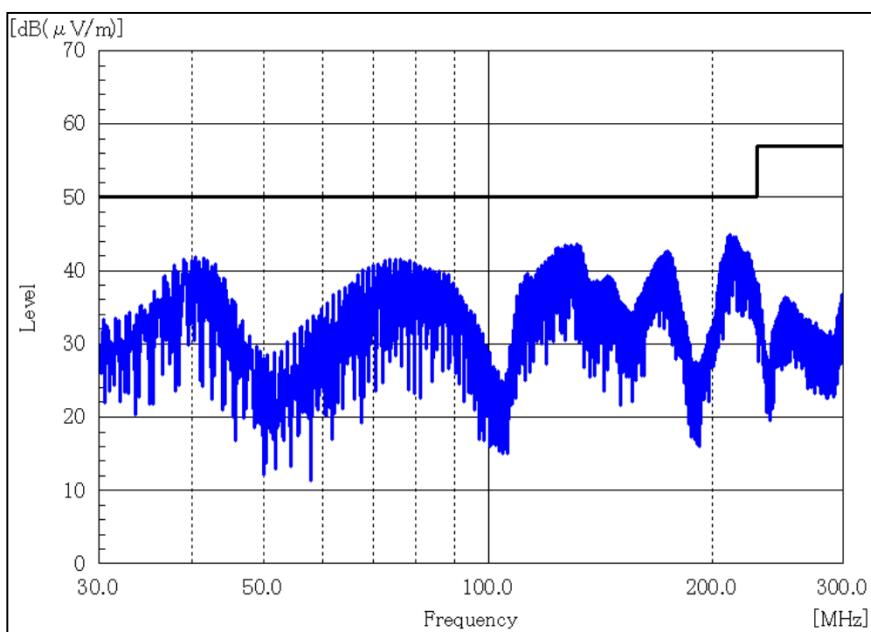
Io : 100 %

Tbp : 25 °C

24V

HORIZONTAL

VCCI classA
QP Limit
(Distance: 3m)

VERTICAL

VCCI classA
QP Limit
(Distance: 3m)

EN55011-A, EN55032-Aの限界値は、VCCI ClassAの限界値と同じ

Limit of EN55011-A, EN55032-A are same as its VCCI ClassA.

2.10 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

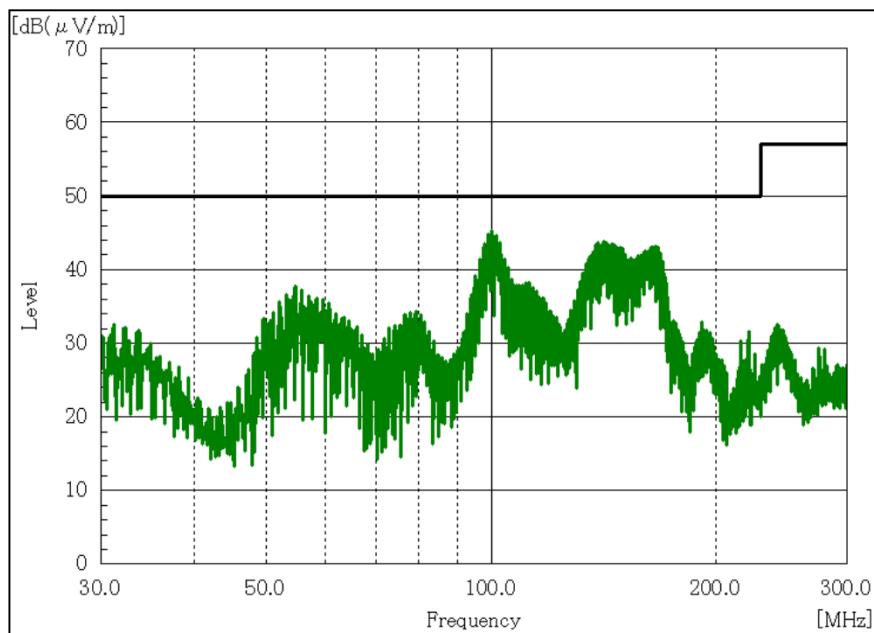
Conditions

Vin : 280 VDC

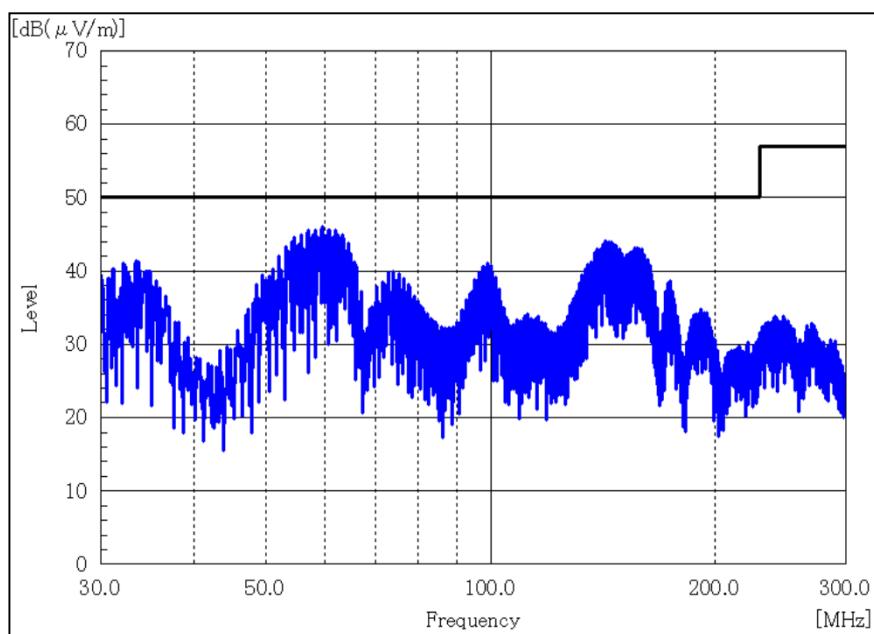
Io : 100 %

Tbp : 25 °C

48V

HORIZONTAL

VCCI classA
QP Limit
(Distance: 3m)

VERTICAL

VCCI classA
QP Limit
(Distance: 3m)

EN55011-A, EN55032-Aの限界値は、VCCI ClassAの限界値と同じ

Limit of EN55011-A, EN55032-A are same as its VCCI ClassA.